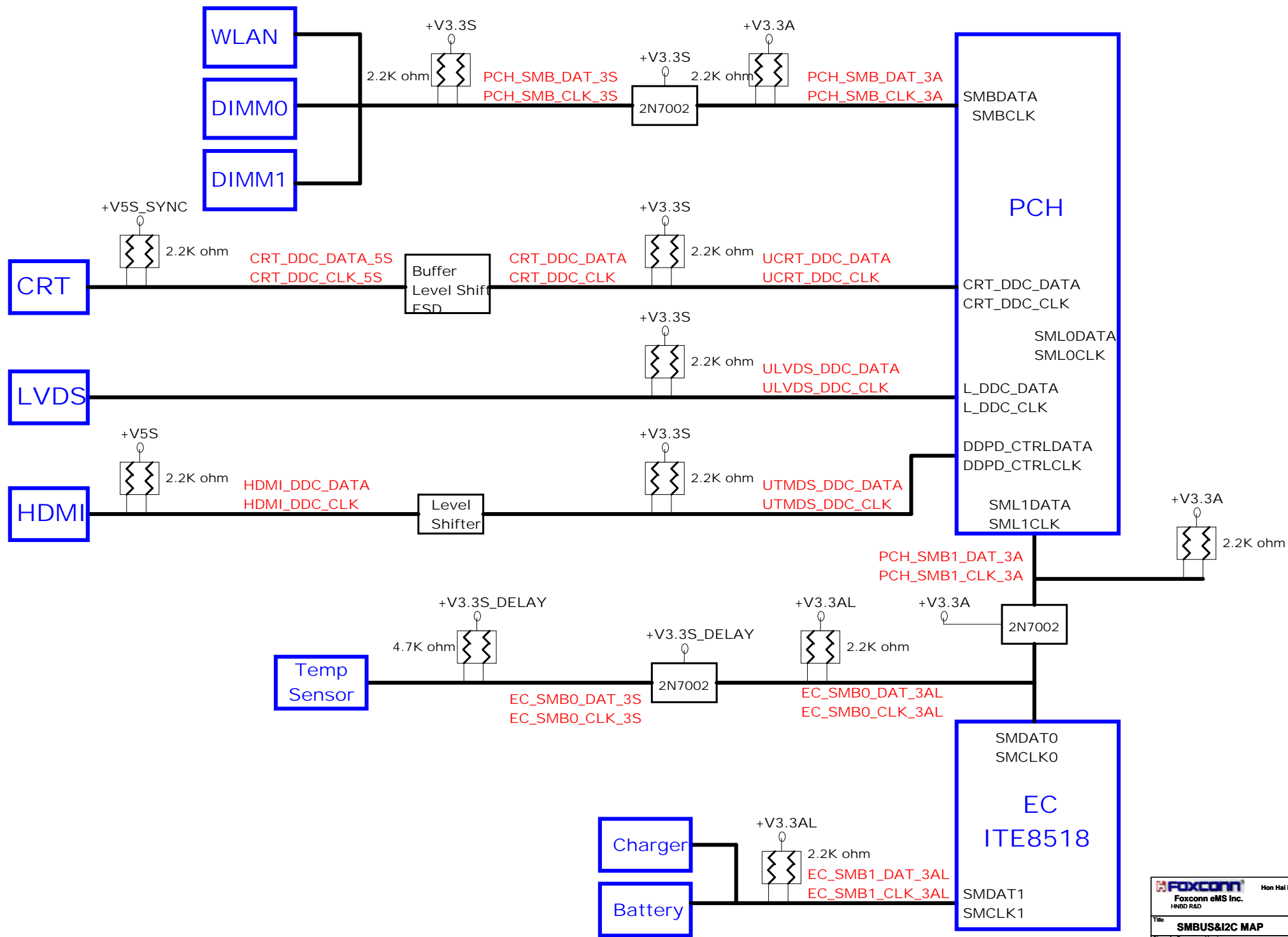


POWER MAP



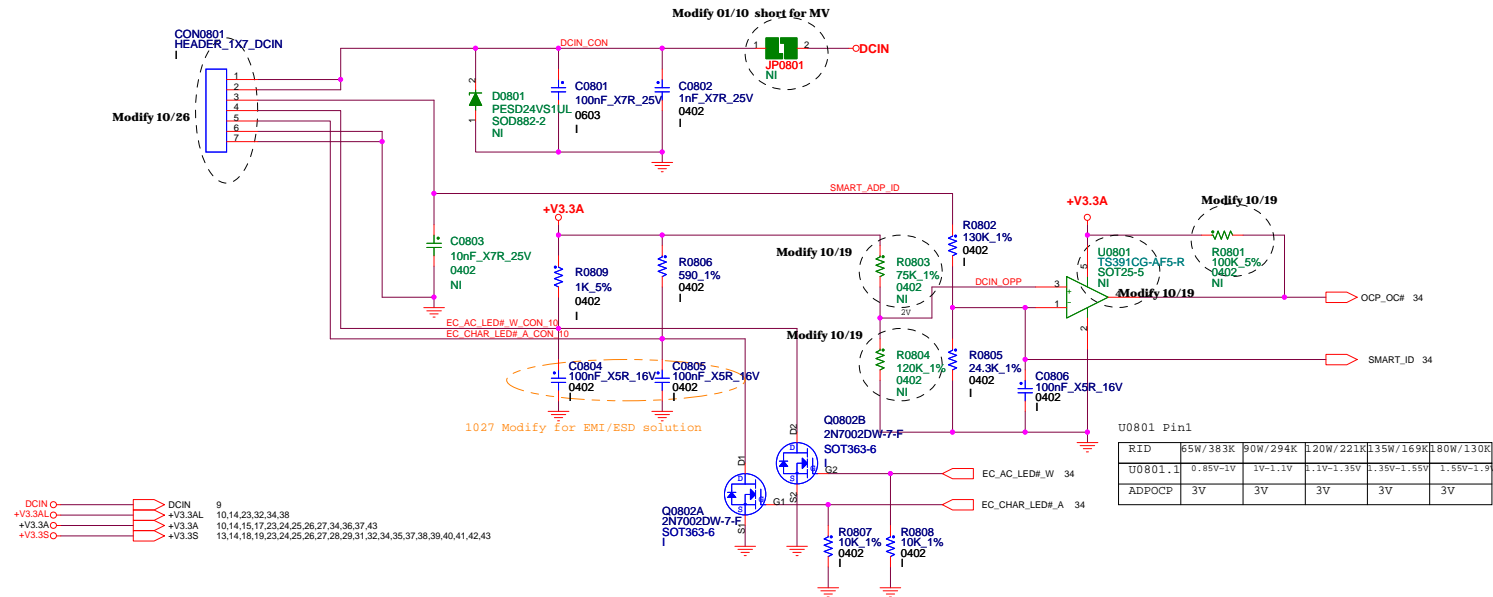


	5	4	3	2	1
D					D
C					C
B					B
A					A
	5	4	3	2	1

 <div> <div>Hon Hai Precision Industry Co. Ltd.</div> <div> <div>Foxconn eMS Inc.</div> <div>HNBD R&D</div> </div> </div>		<div>phone: +886-2-2799-6111</div>
<div>Title</div> <div>BLANK</div>		
<div>Size</div> <div>A</div>	<div>Document Number</div> <div>CHICAGO</div>	<div>Rev</div> <div>MV</div>
<div>Page Modified: Tuesday, March 08, 2011</div> <div>08:28:58 (UTC/GMT)</div> <div>Sheet 7 of 43</div>		

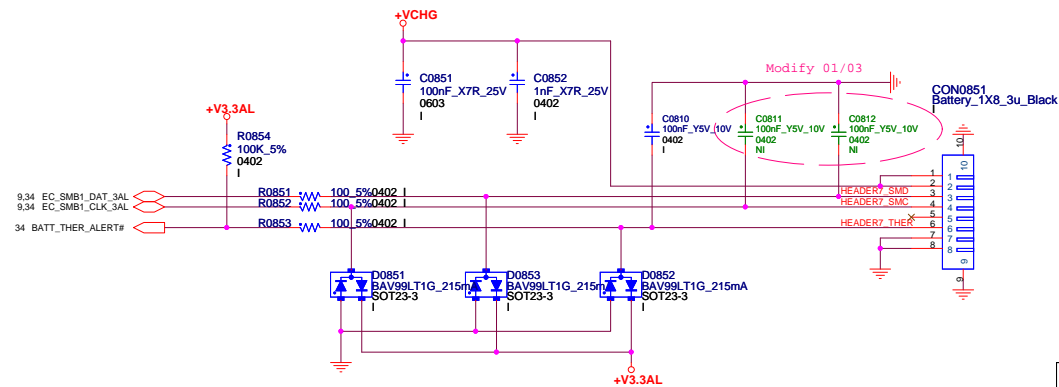
DC_JACK WIRE to BOARD CONNECTOR

2010.1203.0



BATTERY CONNECTOR

2010.0914.0



[illegible]

TRAVELADP	DCIN_RANGE	AC_OFF	CHARGE
>2.412V	>17V	LOW	YES
1.844V<->2.412V	13V<->17V	LOW	NO
<1.844V	<13V	HIGH	NO

8.34 EC_SMB1_CLK_3AL

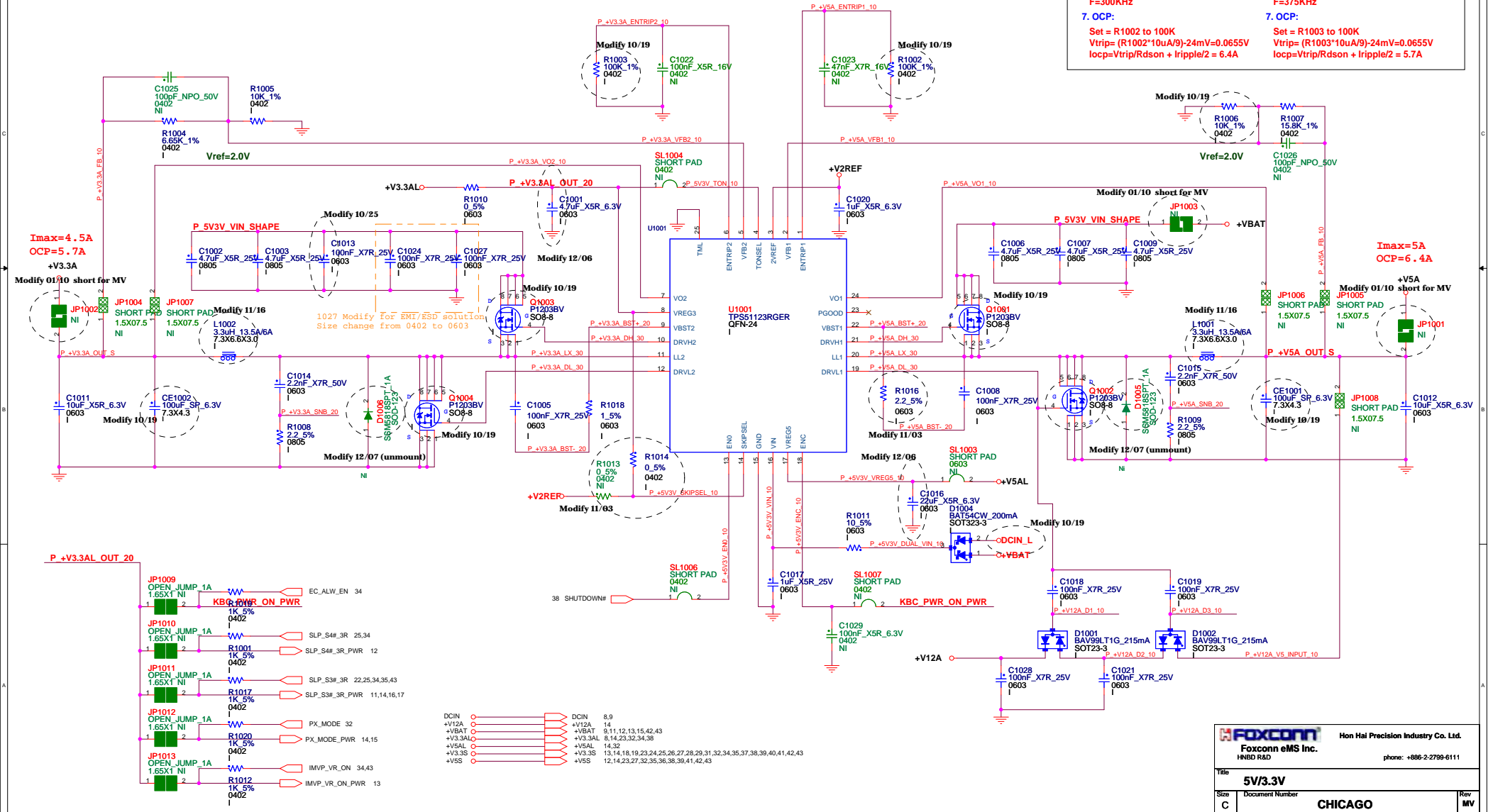
8,34 EC_SMB1_DAT_3AL

DCIN	8
+VBAT	10,11,12,13,15,42,43
+VCHG	8
+V3.3AL	8,10,14,23,32,34,38

+V5A / +V3.3A POWER SUPPLY

2010.1103.0

+V5A: 1. I/P Current: $I_{in} = V_o \cdot I_o / (0.75 \cdot V_{in}) = 3.7A$ 2. Ripple Current: $I_{rip} = 3.72A$ 3. Ripple Voltage: $ESR/1 = 15mohm$ $V_{rip} = 55.8mV$ 4. Inductor Spec: $I_{sat} = 13.5A$ $I_{dc} = 6A$ $DCR = 30mohm$ 5. MOSFET Spec: H-side MOSFET: IRF8707PBF $R_{ds(ON)} = 17.5mohm$ ($V_{gs} = 4.5V$) $I_{cont} = 11A$ ($T = 25^\circ C$) $I_{peak} = 88A$ (Pause $\geq 10us$) 6. Frequency: $F = 300KHz$ 7. OCP: $Set = R1002 \text{ to } 100K$ $V_{trip} = (R1002 \cdot 10uA/9) - 24mV = 0.0655V$ $I_{ocp} = V_{trip} / R_{dson} + I_{ripple} / 2 = 6.4A$	+V3.3A: 1. I/P Current: $I_{in} = V_o \cdot I_o / (0.75 \cdot V_{in}) = 2.2A$ 2. Ripple Current: $I_{rip} = 2.21A$ 3. Ripple Voltage: $ESR/1 = 15mohm$ $V_{rip} = 33.15mV$ 4. Inductor Spec: $I_{sat} = 13.5A$ $I_{dc} = 6A$ $DCR = 30mohm$ 5. MOSFET Spec: L-side MOSFET: IRF8707PBF $R_{ds(ON)} = 17.5mohm$ ($V_{gs} = 4.5V$) $I_{cont} = 11A$ ($T = 25^\circ C$) $I_{peak} = 88A$ (Pause $\geq 10us$) 6. Frequency: $F = 375KHz$ 7. OCP: $Set = R1003 \text{ to } 100K$ $V_{trip} = (R1003 \cdot 10uA/9) - 24mV = 0.0655V$ $I_{ocp} = V_{trip} / R_{dson} + I_{ripple} / 2 = 5.7A$
--	---

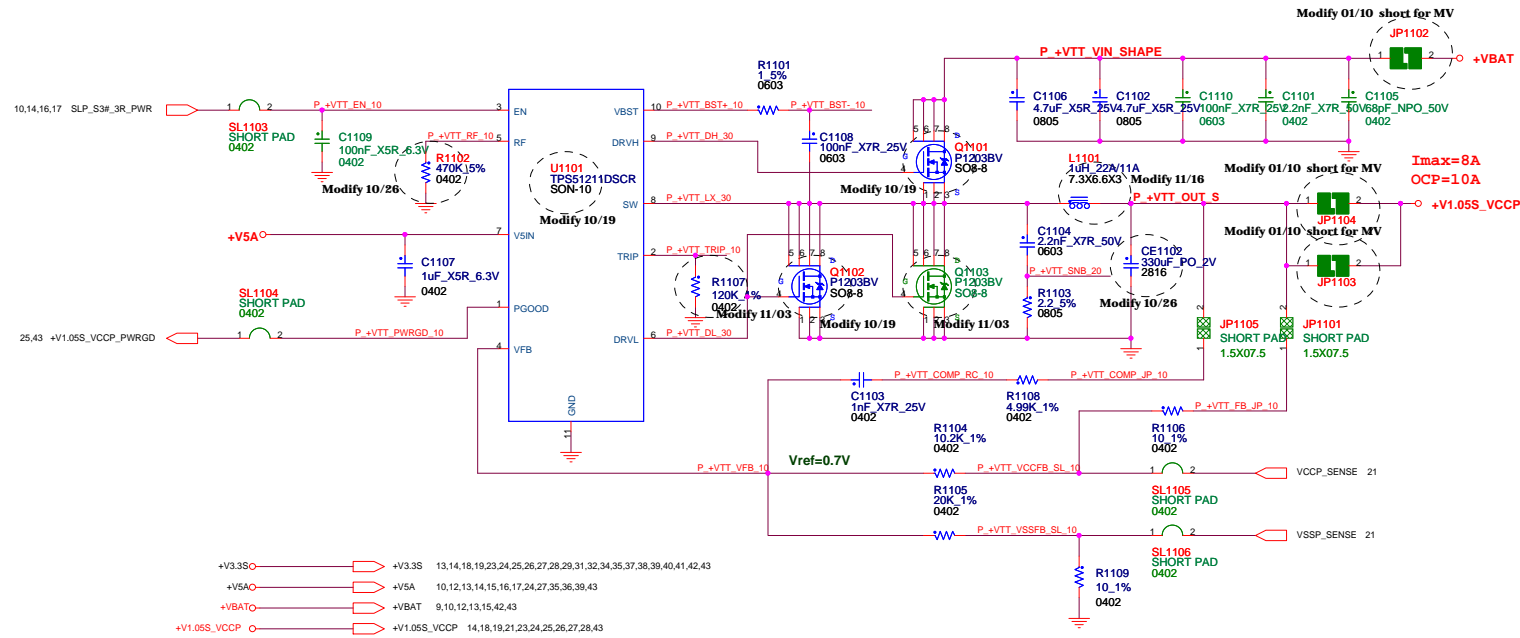


2010.1103.0

+V1.05S_VCCP:

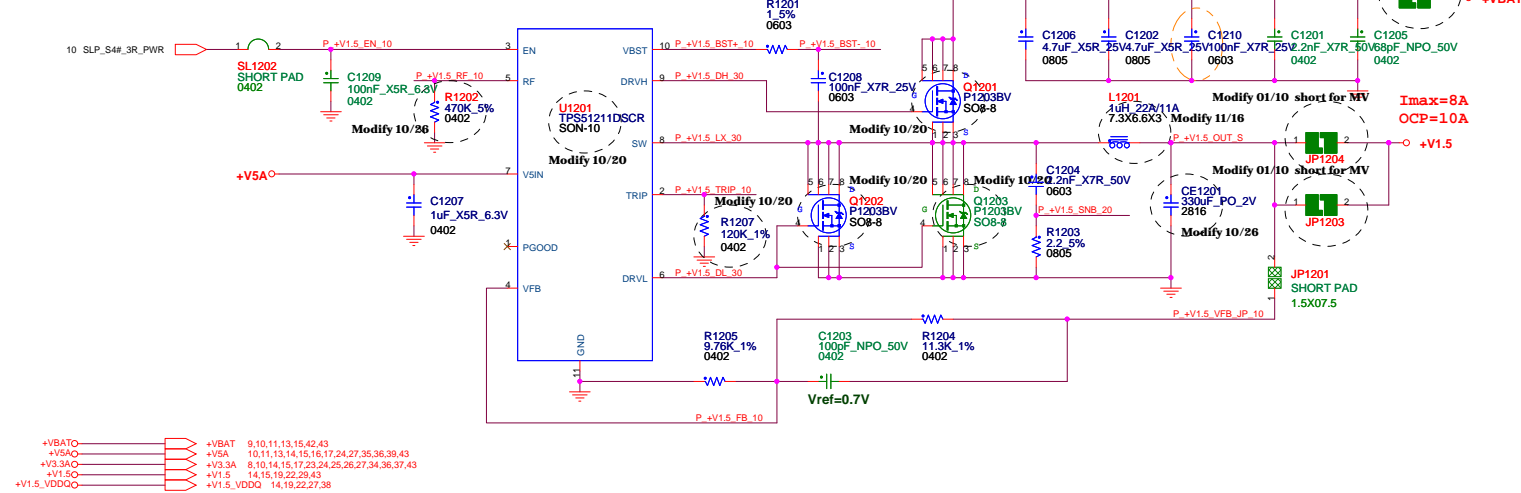
1. I/P Current:
 $I_{in} = V_o \cdot I_o / (0.75 \cdot V_{in}) = 1.24A$
2. Ripple Current:
 $I_{rip} = 3.42A$
3. Ripple Voltage:
 $ESR / f = 9m\Omega$
 $V_{rip} = 30.78mV$
4. Inductor Spec:
 $I_{sat} = 36A$
 $I_{dc} = 18A$
 $DCR = 3.3m\Omega$
5. MOSFET Spec:

H-side MOSFET: IRF8707PBF	L-side MOSFET: IRF8707PBF
$R_{ds}(ON) = 17.5m\Omega$ ($V_{gs} = 4.5V$)	$R_{ds}(ON) = 17.5m\Omega$ ($V_{gs} = 4.5V$)
$I_{cont} = 11A$ ($T = 25^\circ C$)	$I_{cont} = 11A$ ($T = 25^\circ C$)
$I_{peak} = 88A$ (Pause = 10 us)	$I_{peak} = 88A$ (Pause = 10 us)
6. Frequency:
 $F = 290KHz$ ($R_{1102} = 0\Omega$)
7. OCP:
 $Set = R_{1107} \text{ to } 120K$
 $V_{trip} = R_{1107} \cdot 10uA = 1.2V$
 $locp = (V_{trip} / 8 \cdot R_{dson}) + I_{ripple} / 2 = 10A$



+V1.5 POWER SUPPLY

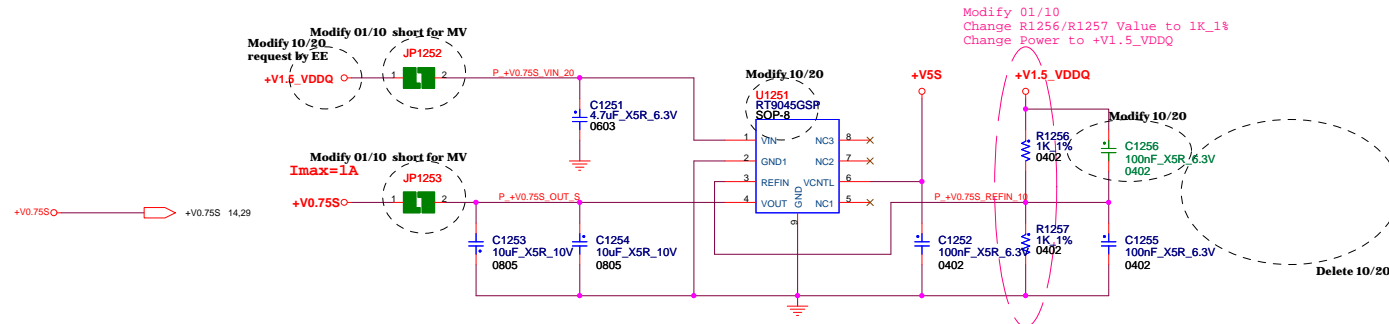
2010.1026.0



- +V1.5:**
- I/P Current:**
 $I_{in} = V_o \cdot I_o / (0.75 \cdot V_{in}) = 1.78A$
 - Ripple Current:**
 $I_{rip} = 3.34A$
 - Ripple Voltage:**
 $ESR/1 = 9mohm$
 $V_{rip} = 30.6mV$
 - Inductor Spec:**
 $I_{sat} = 36A$
 $I_{dc} = 18A$
 $DCR = 3.3mohm$
 - MOSFET Spec:**
 H-side MOSFET: IRF8707PBF
 $R_{ds(ON)} = 17.5mohm$ ($V_{gs} = 4.5V$)
 $I_{cont} = 11A$ ($T = 25^\circ C$)
 $I_{peak} = 88A$ (Pause = 10 us)
 L-side MOSFET: IRF8707PBF
 $R_{ds(ON)} = 17.5mohm$ ($V_{gs} = 4.5V$)
 $I_{cont} = 11A$ ($T = 25^\circ C$)
 $I_{peak} = 88A$ (Pause = 10 us)
 - Frequency:**
 $F = 290KHz$ ($R_{0902} = 0ohm$)
 - OCP:**
 Set = R1207 to 120K
 $V_{trip} = R1207 \cdot 10uA = 1.2V$
 $I_{ocp} = (V_{trip} / 8 \cdot R_{dson}) + I_{ripple} / 2 = 10A$

+V0.75S POWER SUPPLY

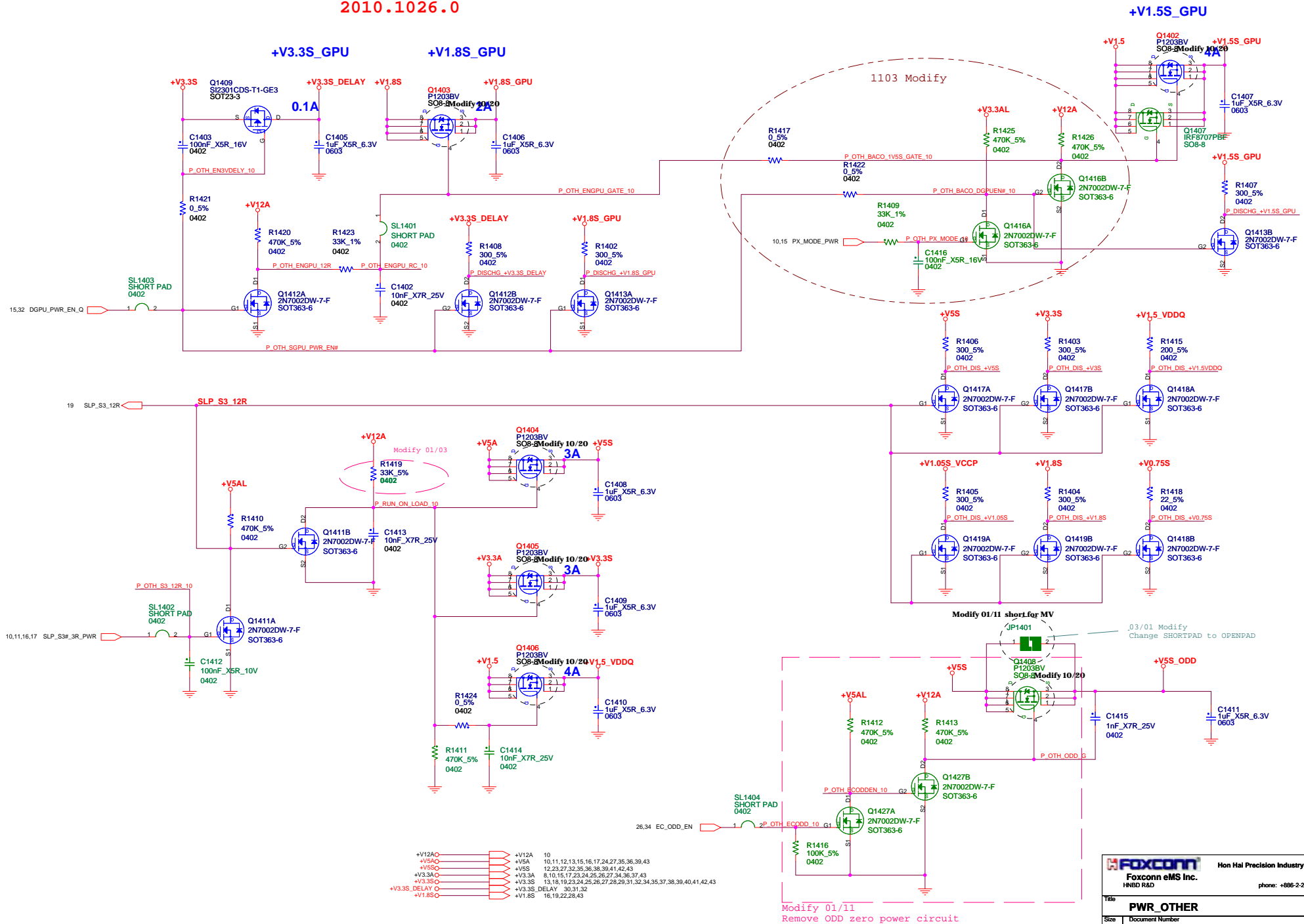
2010.1026.0



2010.1026.0

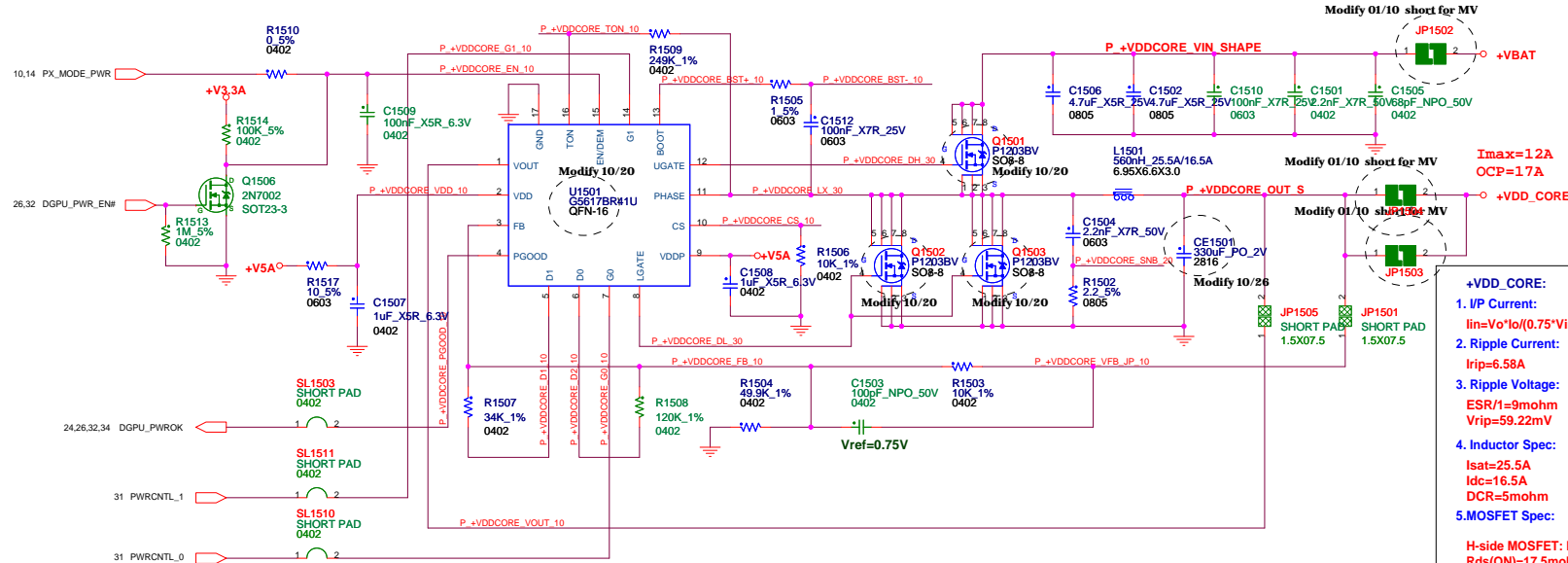


2010.1026.0



+VDD_CORE POWER SUPPLY

2010.1026.0



PWRCNTL_1	PWRCNTL_0	VDD_CORE
0	---	1.121V
---	---	---
1	---	0.9V
---	---	---

+VDD_CORE:

1. IP Current:

$I_{in} = V_o \cdot I_o / (0.75 \cdot V_{in}) = 1.48A$

2. Ripple Current:

$I_{rip} = 6.58A$

3. Ripple Voltage:

$ESR / I = 9m\Omega$

$V_{rip} = 59.22mV$

4. Inductor Spec:

$I_{sat} = 25.5A$

$I_{dc} = 16.5A$

$DCR = 5m\Omega$

5. MOSFET Spec:

H-side MOSFET: IRF8707PBF

$R_{ds(ON)} = 17.5m\Omega$ ($V_{gs} = 4.5V$)

$I_{cont} = 11A$ ($T = 25^\circ C$)

$I_{peak} = 88A$ (Pause = 10 us)

L-side MOSFET: IRF8707PBF

$R_{ds(ON)} = 17.5m\Omega$ ($V_{gs} = 4.5V$)

$I_{cont} = 11A$ ($T = 25^\circ C$)

$I_{peak} = 88A$ (Pause = 10 us)

6. Frequency:

$TON = 9.6 \cdot P \cdot R_{1509} \cdot (V_{OUT} + 0.1) / (V_{IN} - 0.3) + 50ns = 206ns$

$F = V_{OUT} / (V_{IN} \cdot TON) = 286KHz$

7. OCP:

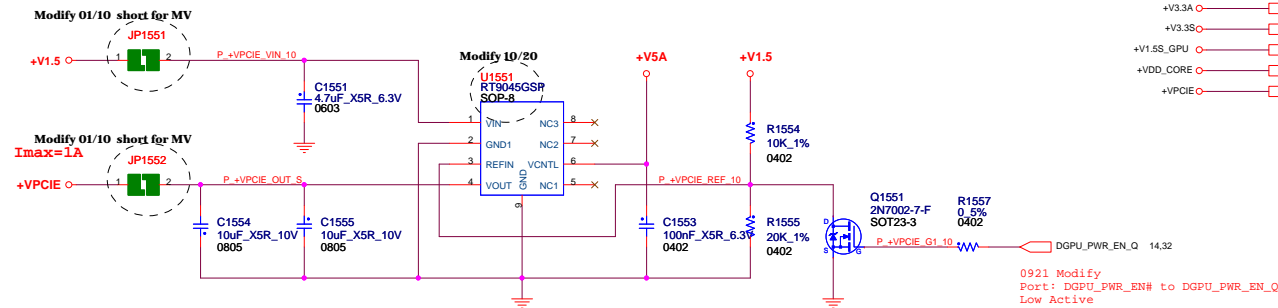
Set = R1506 to 10K

$V_{trip} = R_{1206} \cdot I_{OJA} = 0.1V$

$I_{ocp} = (V_{trip} / R_{ds(on)}) + I_{ripple} / 2 = 17A$

2010.1020.0

+VPCIE POWER SUPPLY



+VBAT	9,10,11,12,13,42,43
+V5A	10,11,12,13,14,16,17,24,27,35,36,39,43
+V3.3A	8,10,14,17,23,24,25,26,27,34,36,37,43
+V3.3S	13,14,18,19,23,24,25,26,27,28,29,31,32,34,35,37,38,39,40,41,42,43
+V1.5S_GPU	14,30,32,33,43
+VDD_CORE	32,43
+VPCIE	30,31,32,43

0921 Modify
Port: DGPU_PWR_EN# to DGPU_PWR_EN_Q
Low Active

+V1.8S POWER SUPPLY

2010.1025.0

+V1.8S:

1. I/P Current:

$$I_{in} = V_o \cdot I_o / (0.75 \cdot V_{in}) = 1.44A$$

2. Ripple Current:

$$I_{rip} = 0.53A$$

3. Ripple Voltage:

$$ESR/3 = 3.3m\Omega$$

$$V_{rip} = 1.75mV$$

4. Inductor Spec:

$$I_{sat} = 14A$$

$$I_{dc} = 8A$$

$$DCR = 20m\Omega$$

5. MOSFET Spec:

H-side P-MOSFET:

L-side N-MOSFET:

$$R_{ds(ON)} = 110m\Omega \quad (V_{gs} = 4.5V)$$

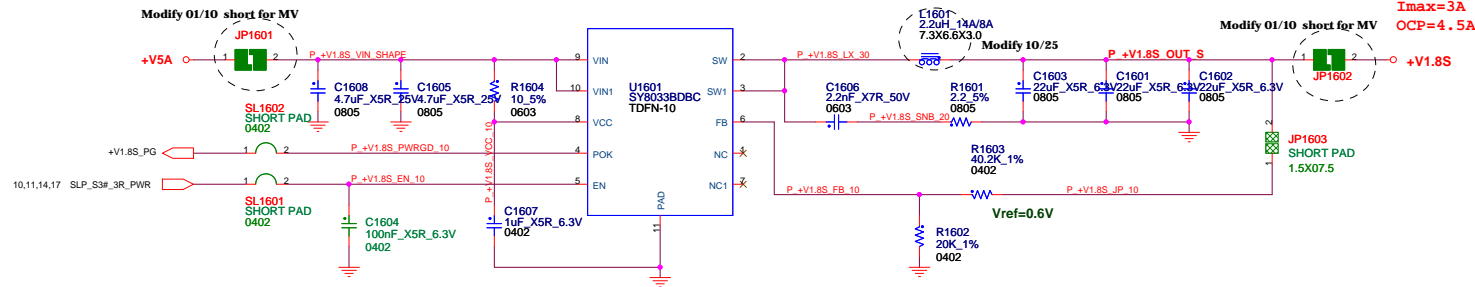
$$R_{ds(ON)} = 75m\Omega \quad (V_{gs} = 4.5V)$$

6. Frequency:

$$F = 1MHz \quad (\min = 800KHz, \max = 1.2MHz)$$

7. OCP:

$$I_{ocp} = 4A(\min) / 4.5A(\text{typ}) / 5A(\max)$$



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Title: +1.8VS

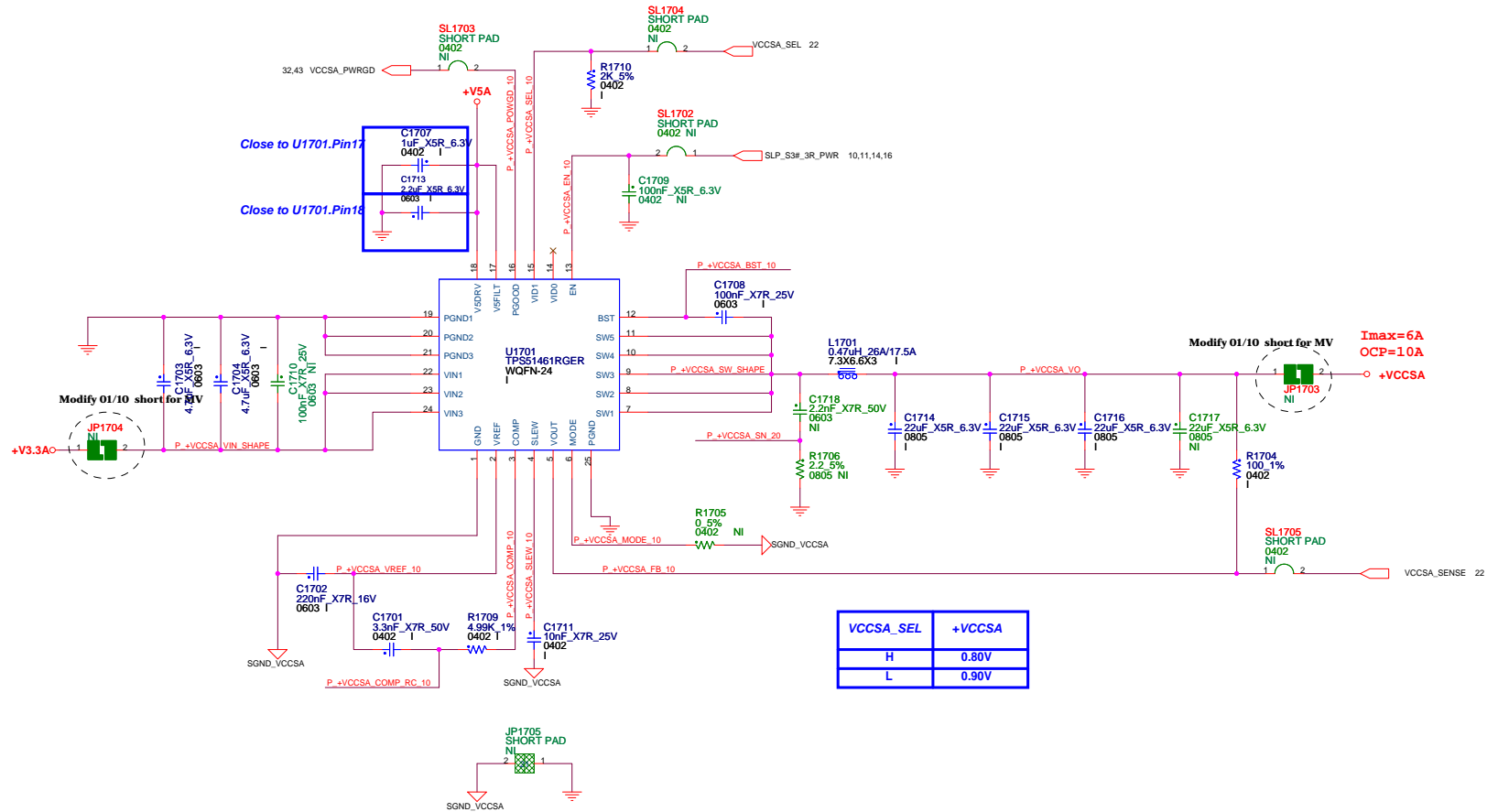
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Page Modified: Tuesday, March 05, 2011 08:28:00 (UTC+08:00) Sheet 16 of 43

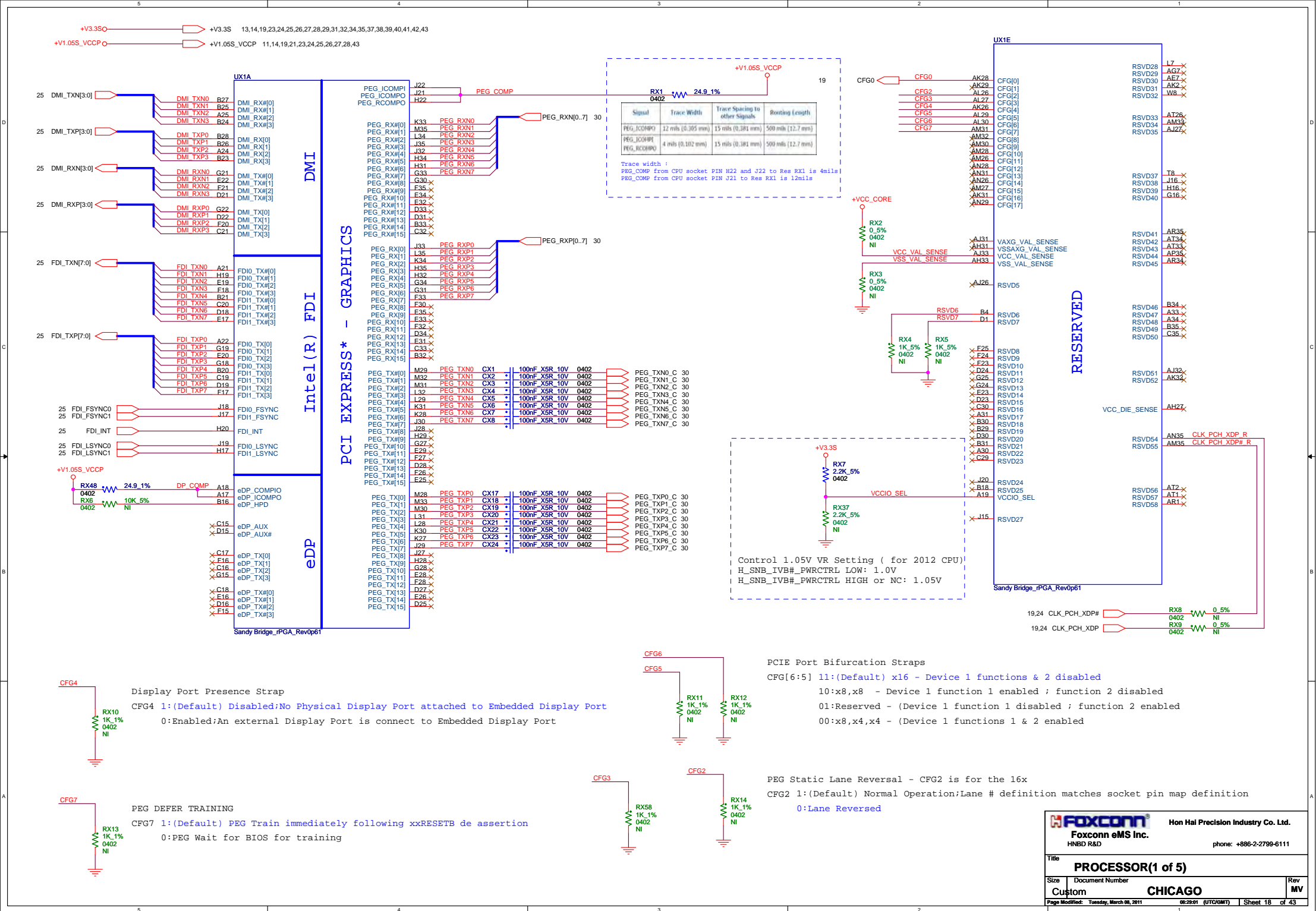
+VCCSA POWER SUPPLY

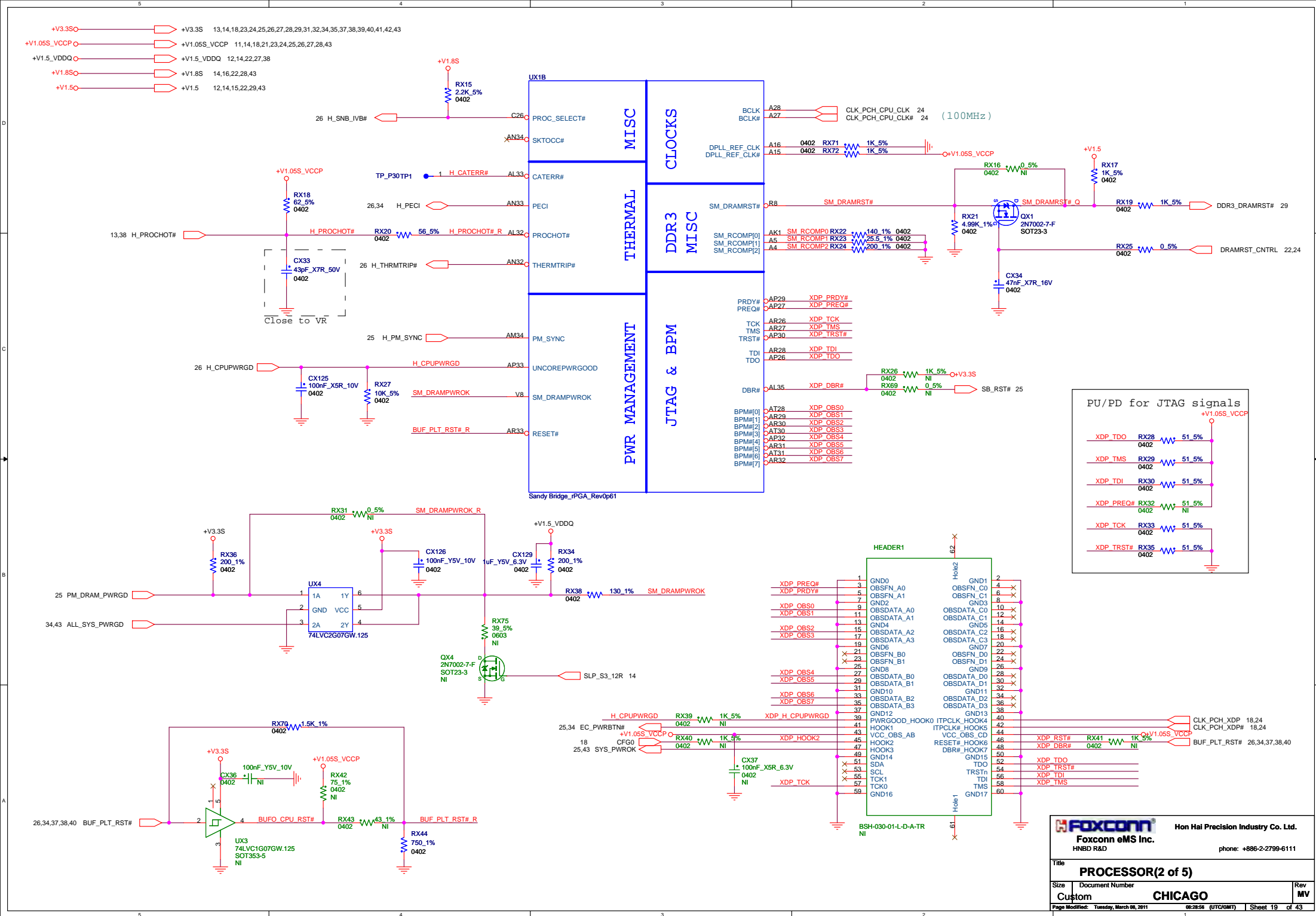
2010.1026.0

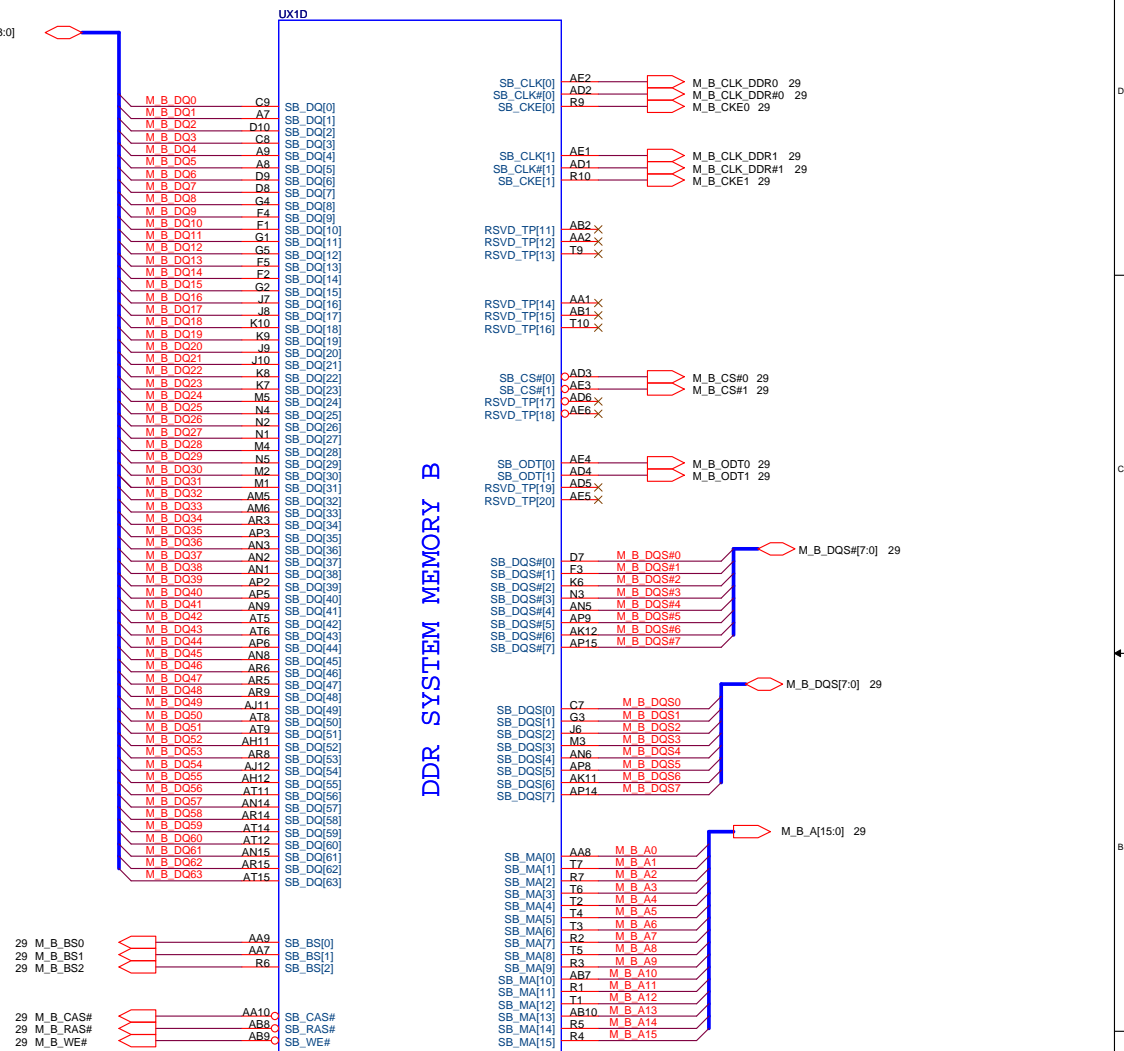
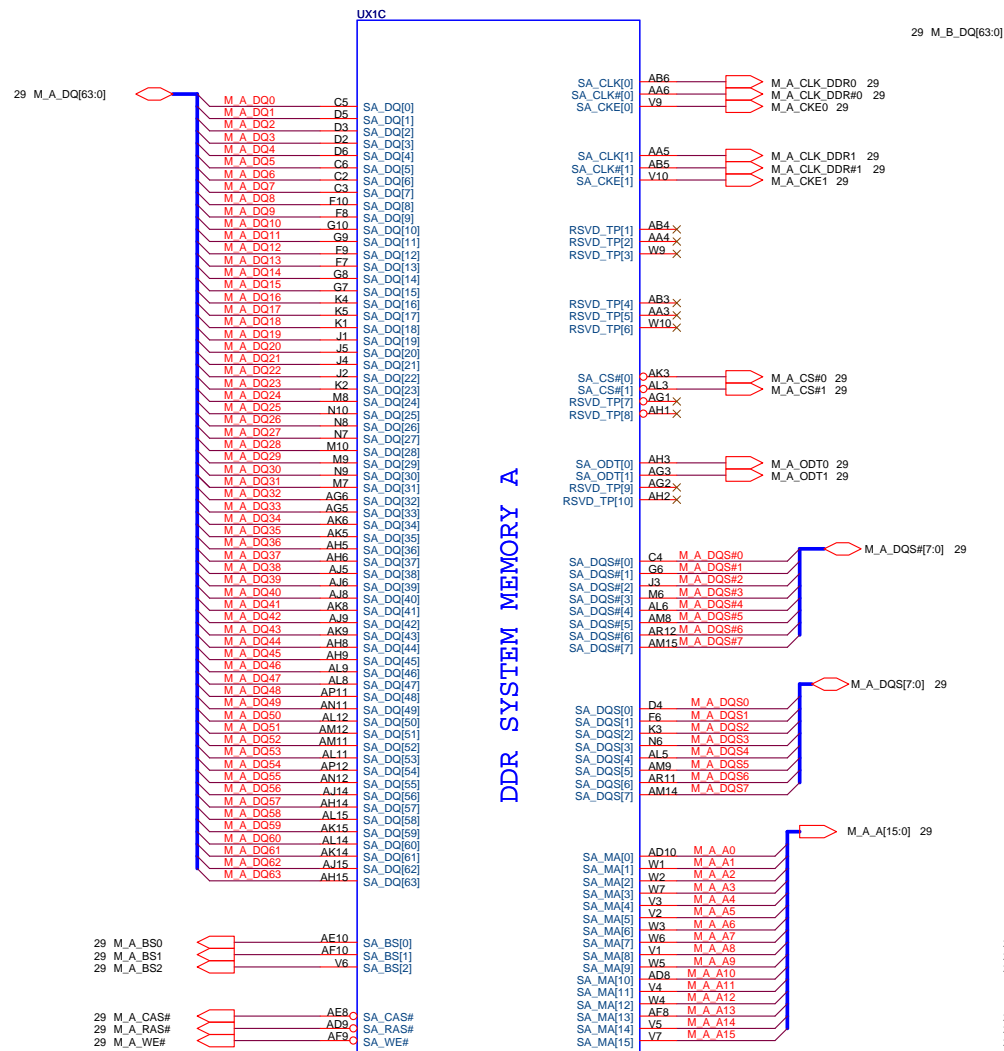


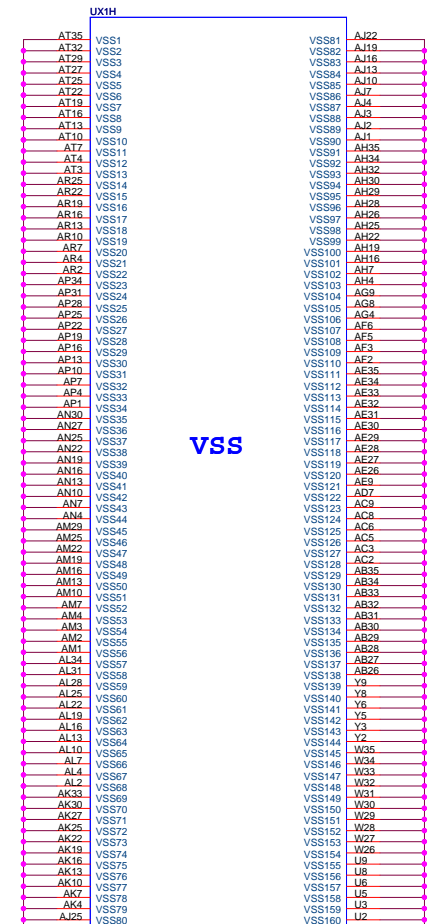
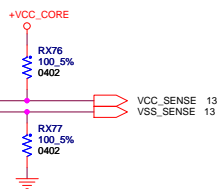
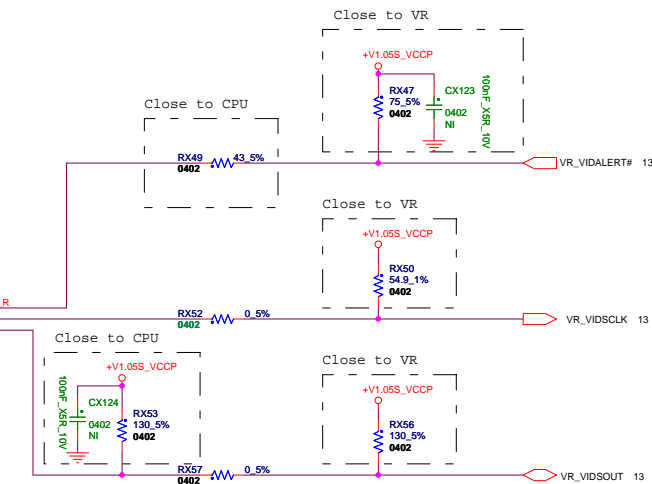
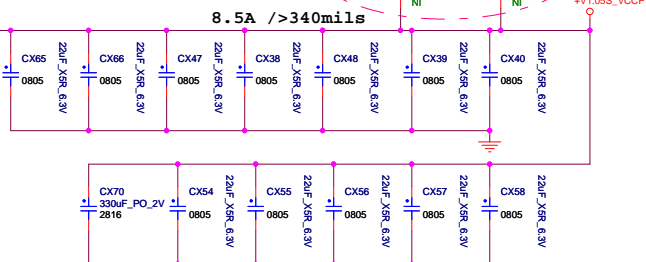
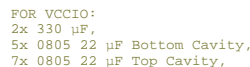
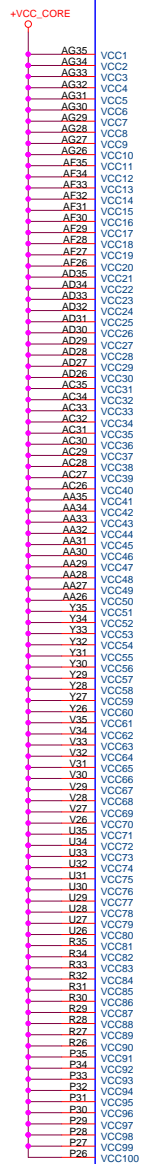
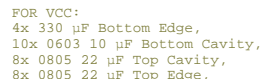
- +VCCSA:**
- 1. I/P Current:**
 $I_{in} = V_o \cdot I_o / (0.75 \cdot V_{in}) = 2.18A$
 - 2. Ripple Current:**
 $I_{rip} = 1.39A$
 - 3. Ripple Voltage:**
 $ESR/4 = 1m\Omega$
 $V_{rip} = 1.39mV$
 - 4. Inductor Spec:**
 $I_{sat} = 26A$
 $I_{dc} = 17.5A$
 $DCR = 4.2m\Omega$
 - 5. MOSFET Spec:**

- 6. Frequency:**
 $F = 1MHz$ (R1705=Open)
- 7. OCP:**
Min : 6A / Typ : 7.5A









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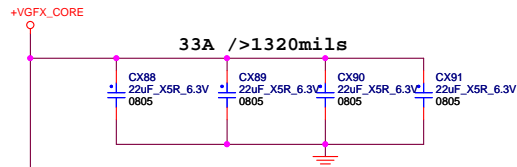
Hon Hai Precision Industry Co. Ltd

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Title **PROCESSOR(4 of 5)**

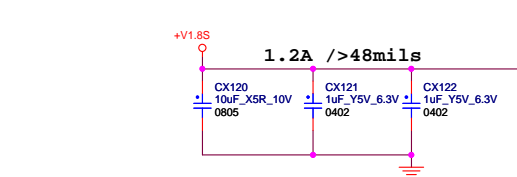
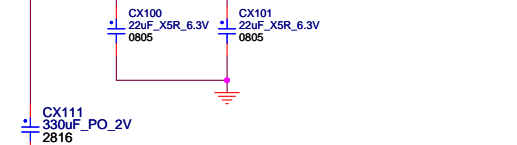
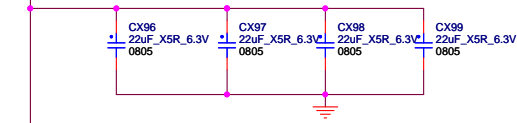
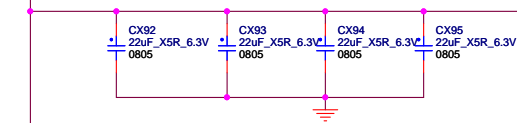
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Custom	CHICAGO

Page Modified: Tuesday, March 08, 2011 08:29:00 (UTC/GMT) Sheet 21 of

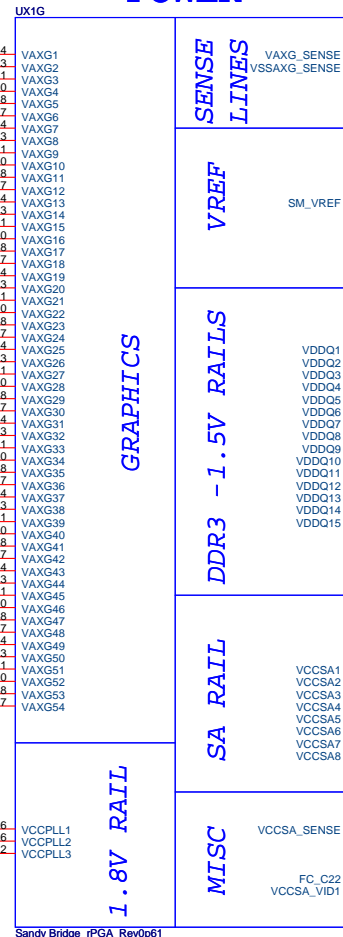


FOR VAXG:
 2x 330 μ F Bottom Edge,
 4x 0805 22 μ F Top & Bottom Cavity,
 8x 0805 22 μ F Top & Bottom Edge,

POWER



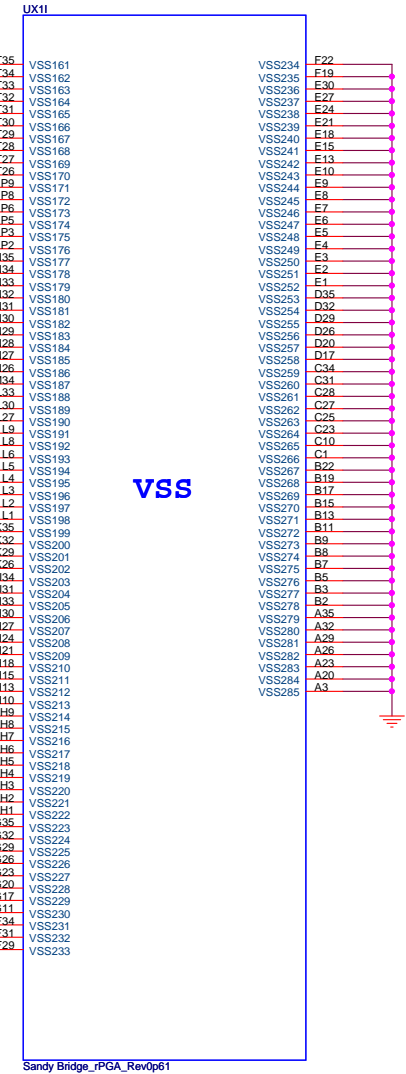
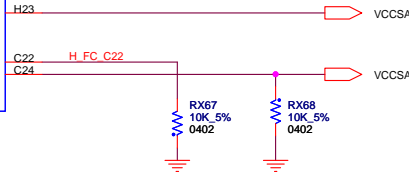
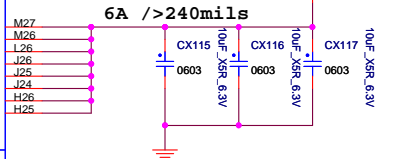
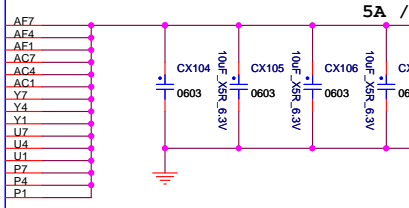
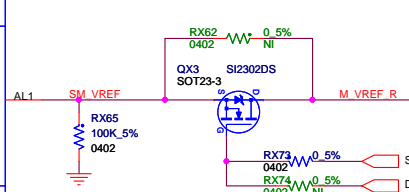
FOR VCCPLL:
 1x 330 μ F Bottom Edge,
 2x 0402 1 μ F Bottom Edge,
 1x 0805 10 μ F Bottom Edge,



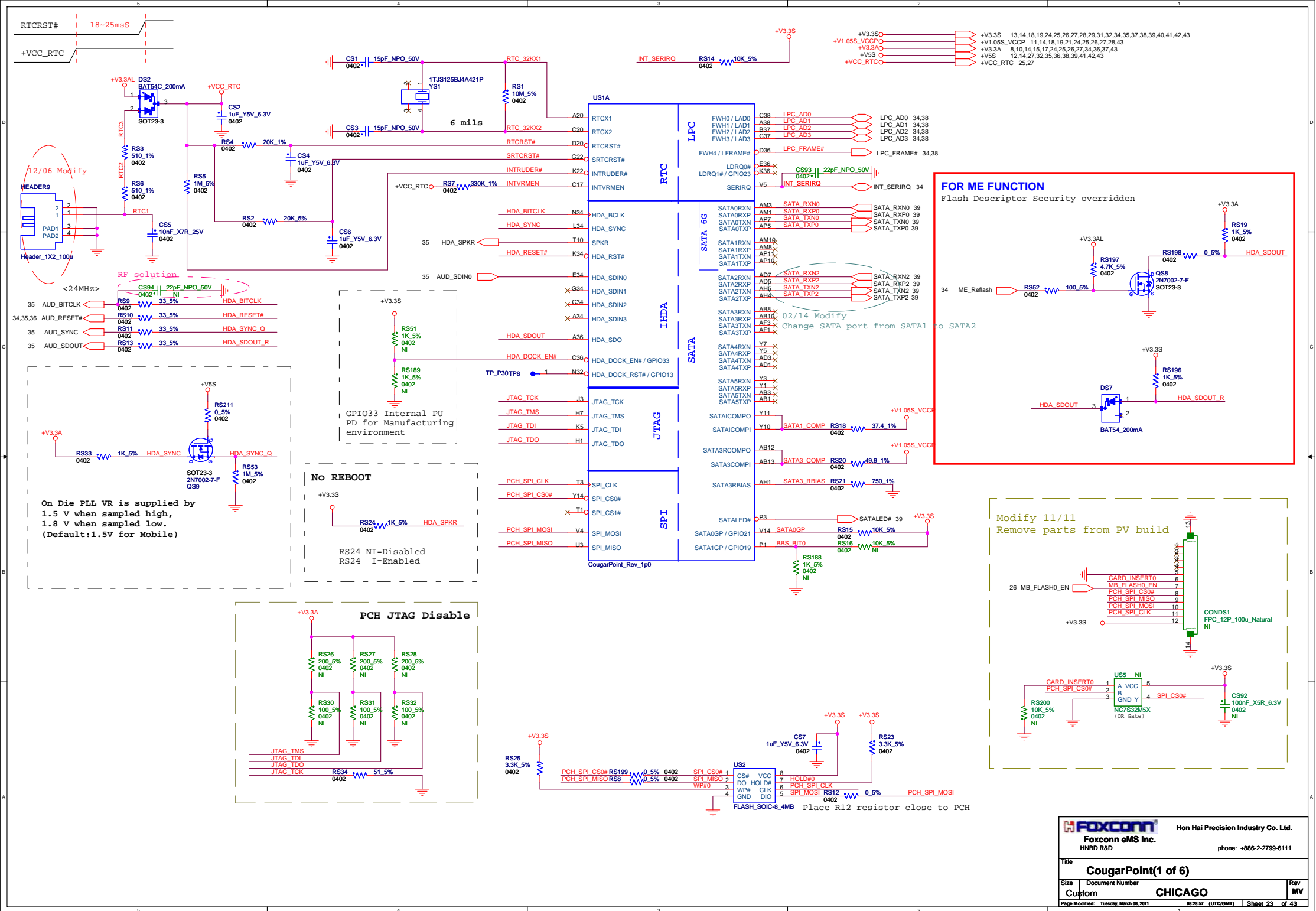
Sandy Bridge_rPGA_Rev0p61

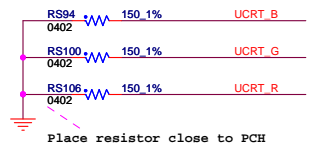
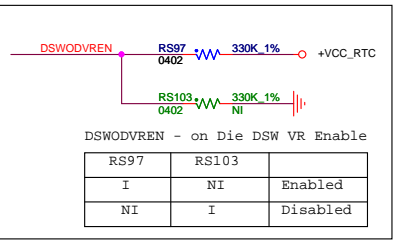
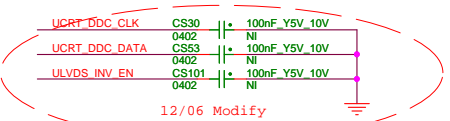
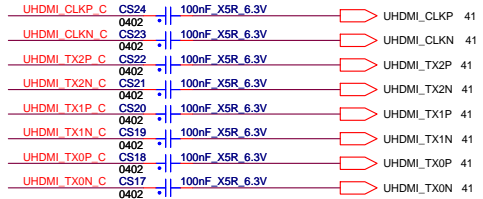
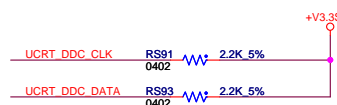
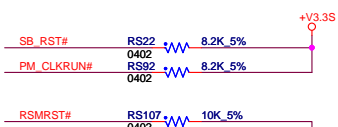
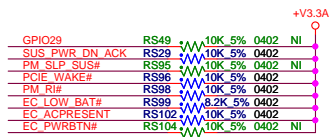
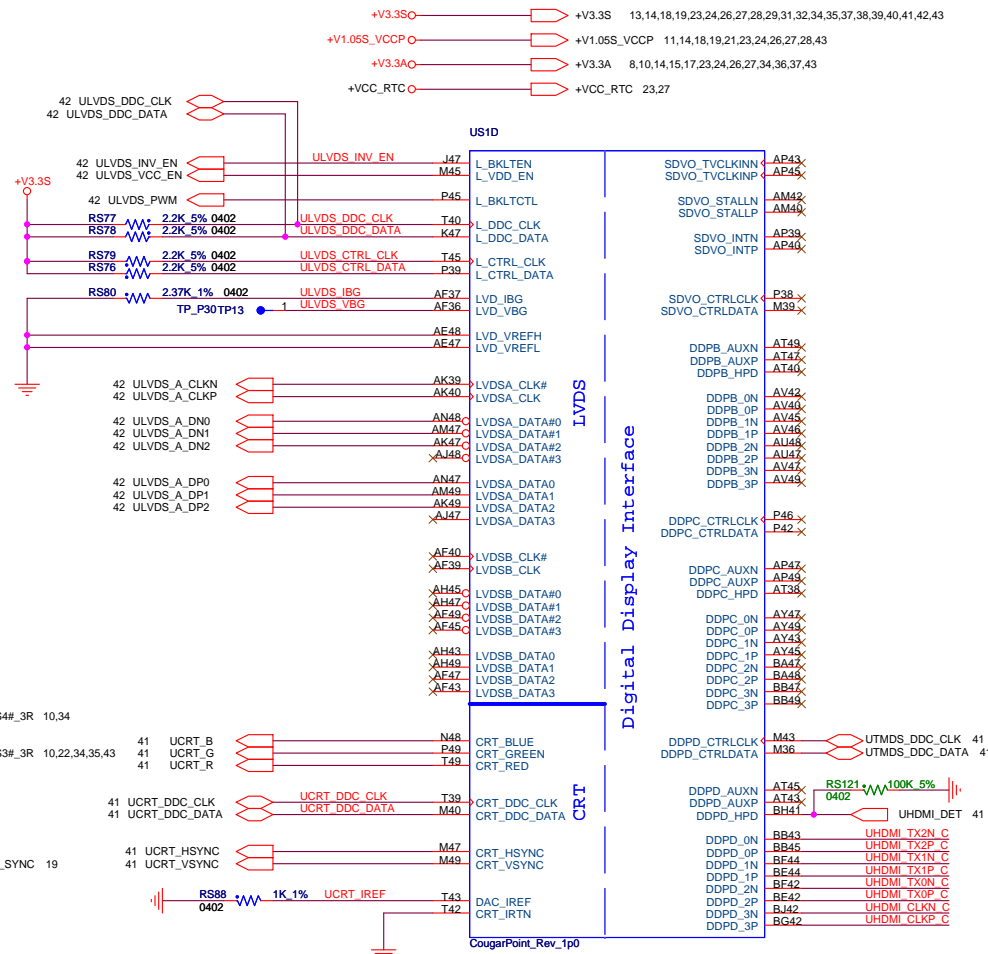
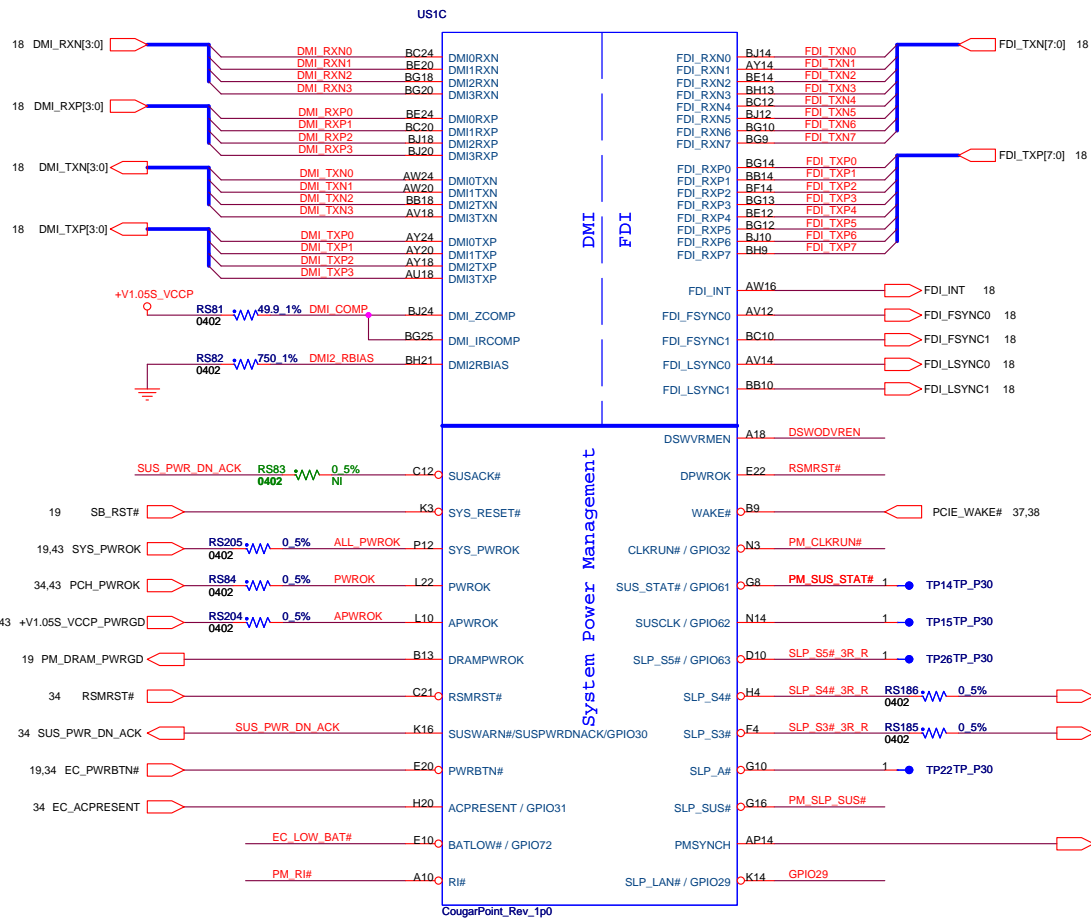
+VCCSAO \rightarrow +VCCSA 17
 +V1.8SQ \rightarrow +V1.8S 14,16,19,28,43
 +V1.5O \rightarrow +V1.5 12,14,15,19,29,43
 +V1.5_VDDQO \rightarrow +V1.5_VDDQ 12,14,19,27,38
 +VGFX_COREO \rightarrow +VGFX_CORE 13,43

AK35 \rightarrow GFX_VCC_SENSE 13
 AK34 \rightarrow GFX_VSS_SENSE 13



Sandy Bridge_rPGA_Rev0p61

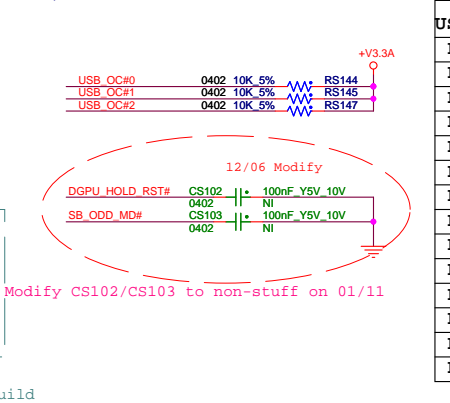
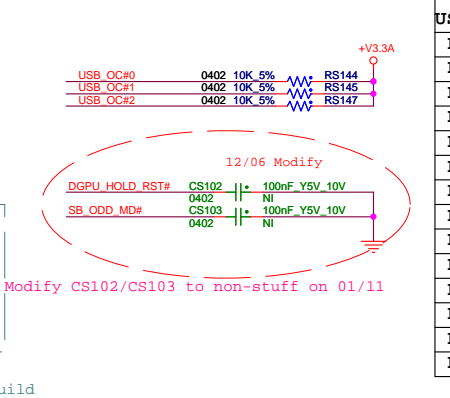




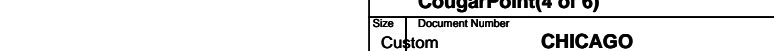
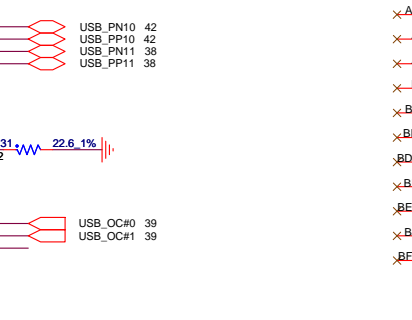
12/06 Modify

Modify CS30/CS53/CS101 to non-stuff on 01/11

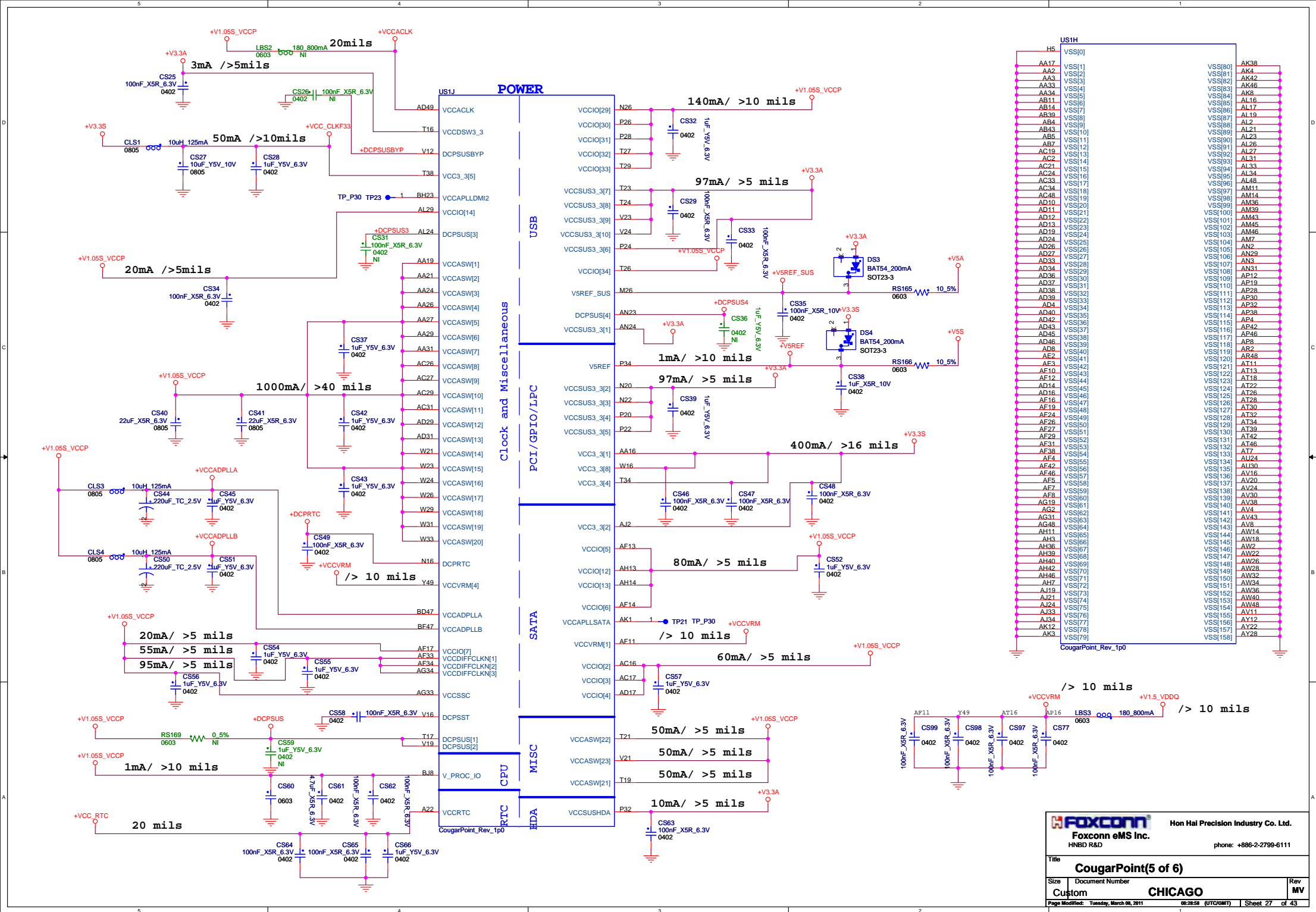
Modify
the PV

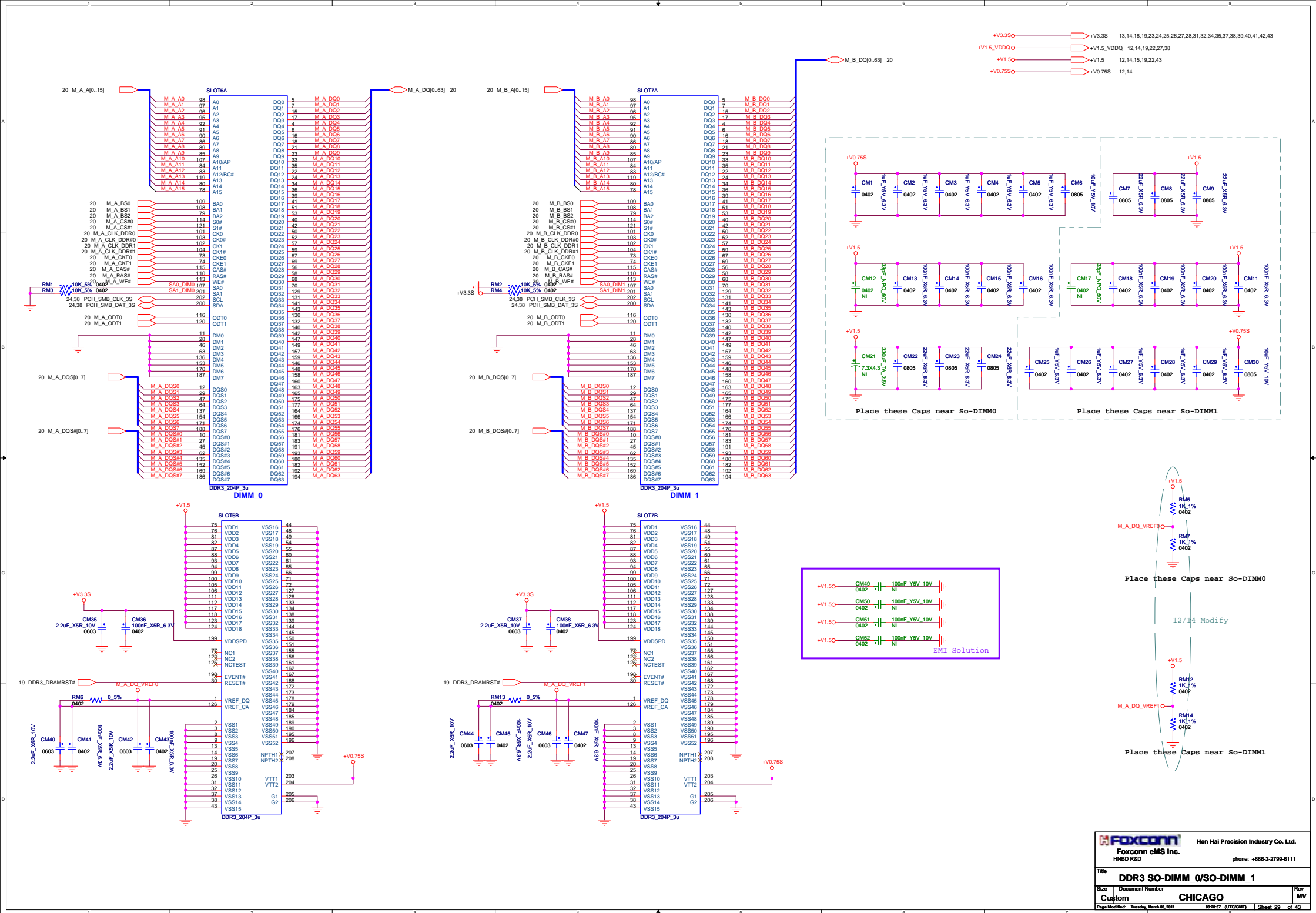


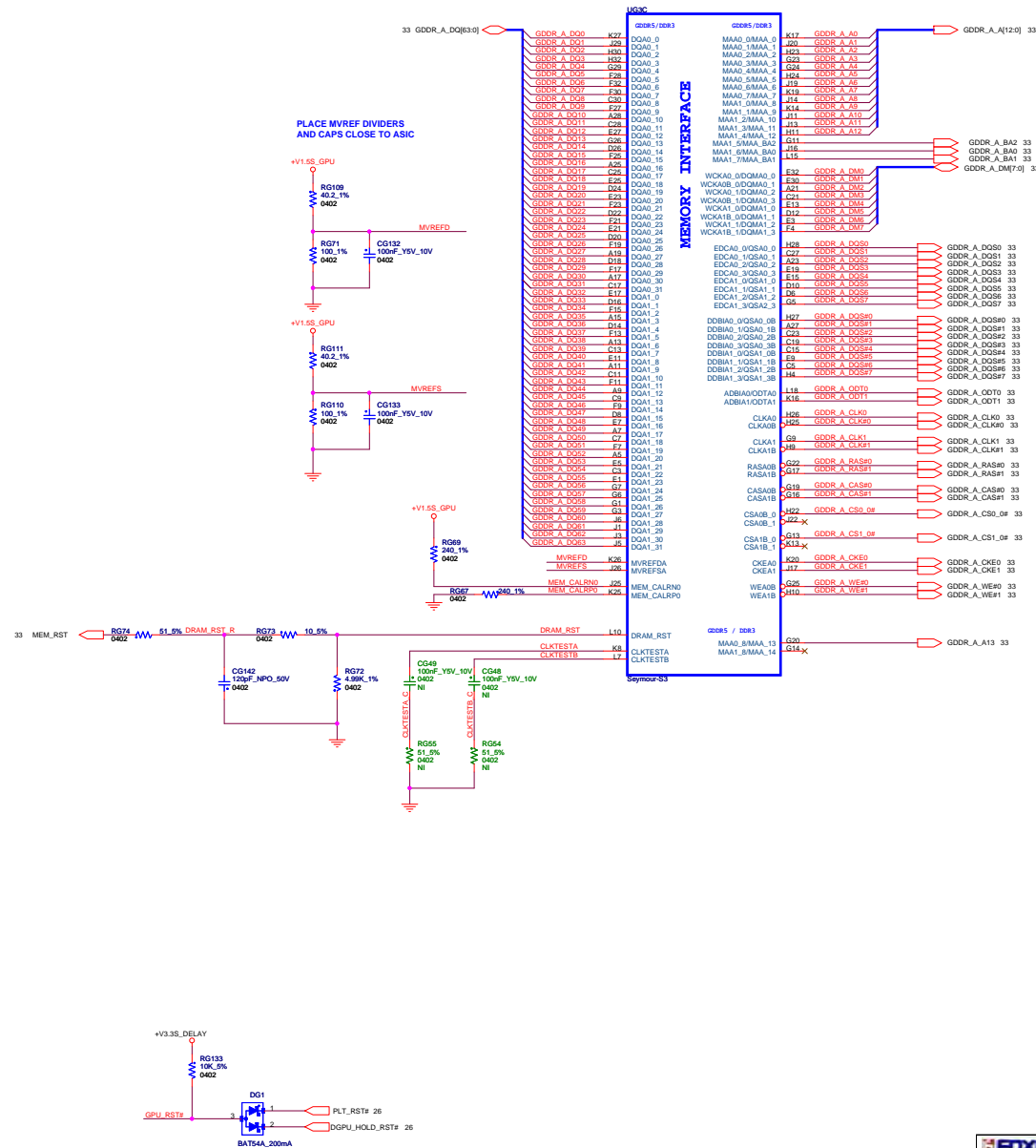
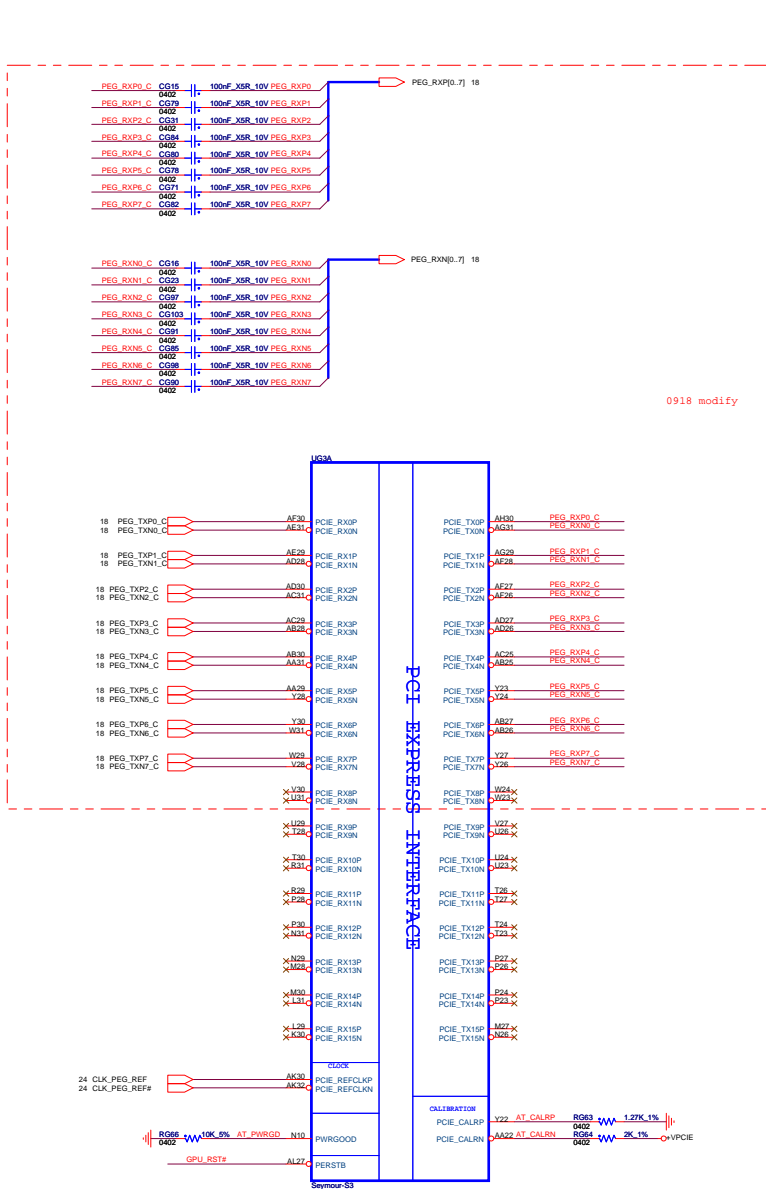
3

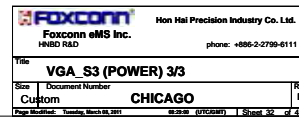


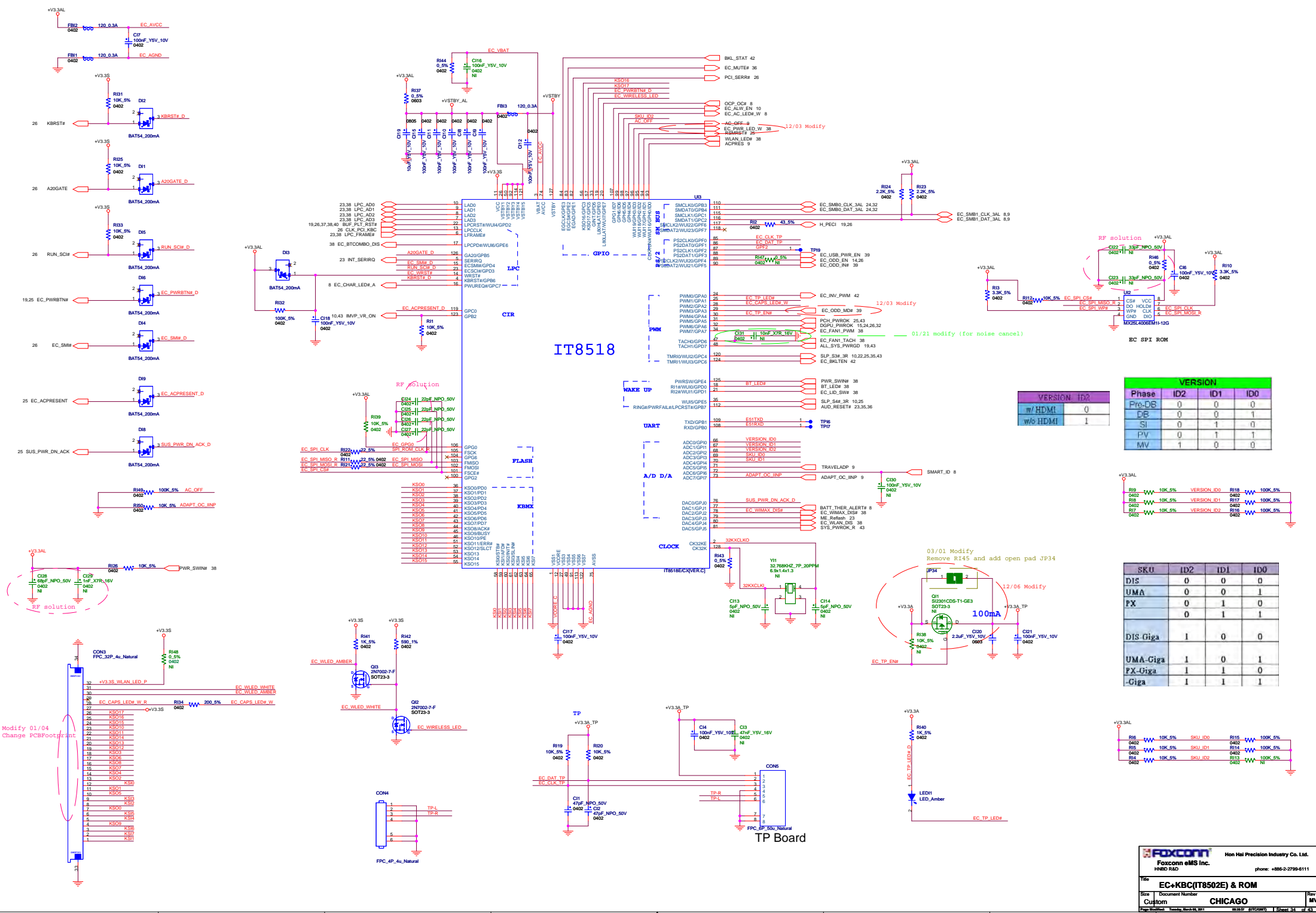
RS132 0402 10K 5% GPIO28 RS130 0402 1K 5% NI
 RS195 0402 10K 5% GPIO24 RS137 0402 10K 5% GPIO12 RS138 0402 1K 5% MB_FLASH0_EN







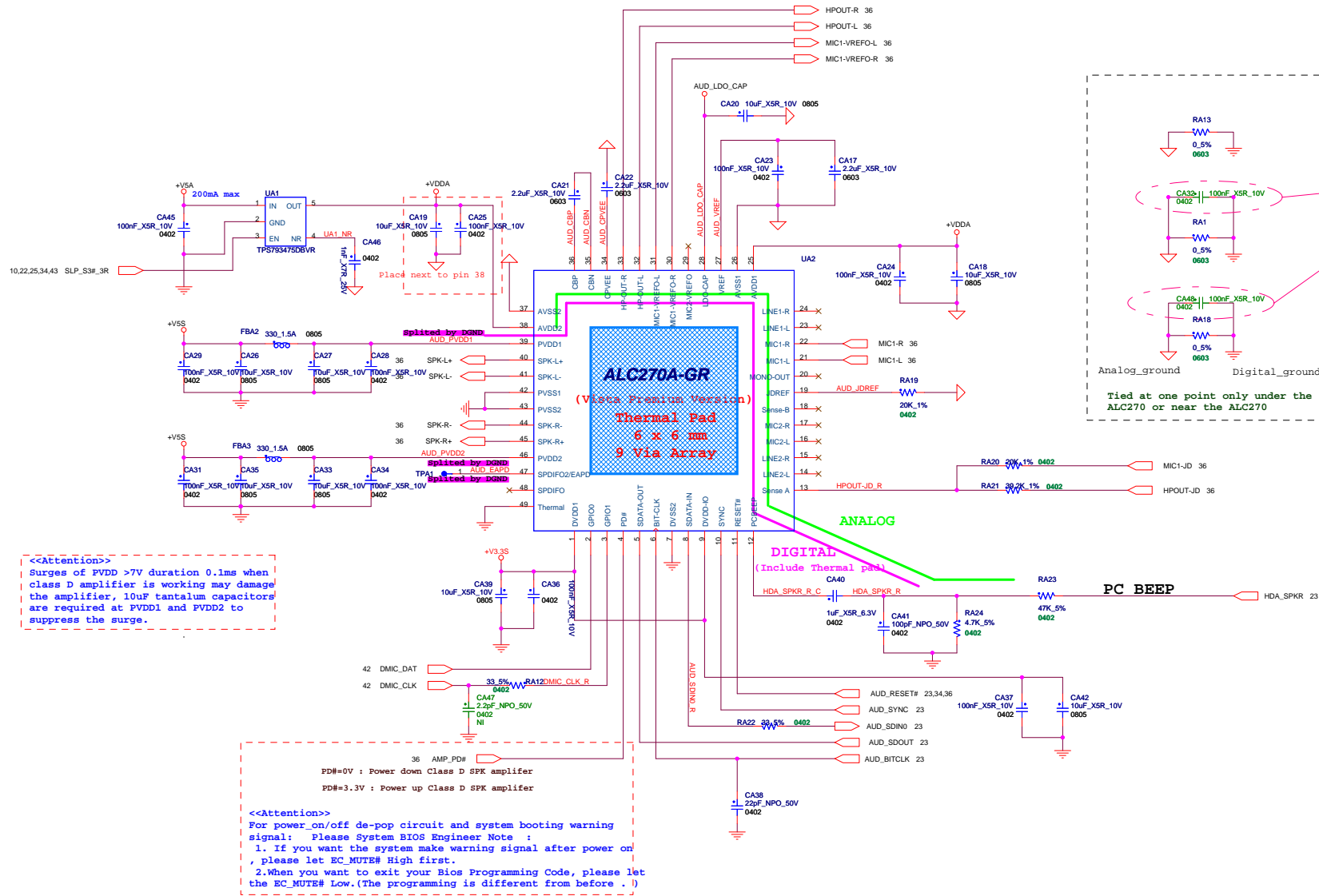


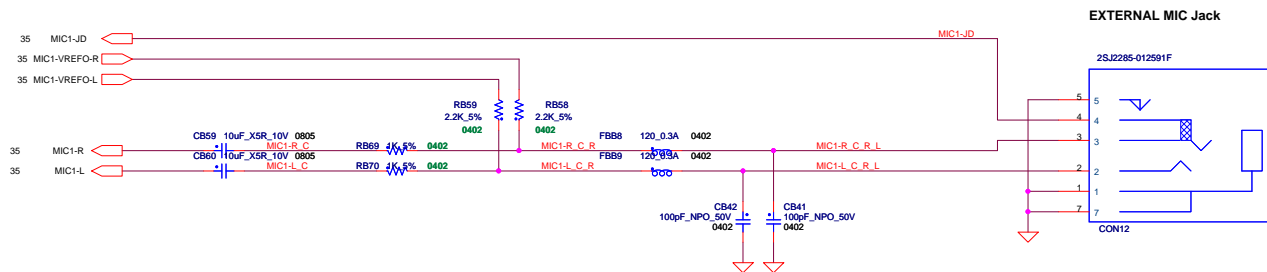
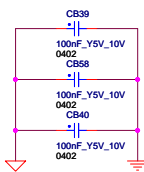
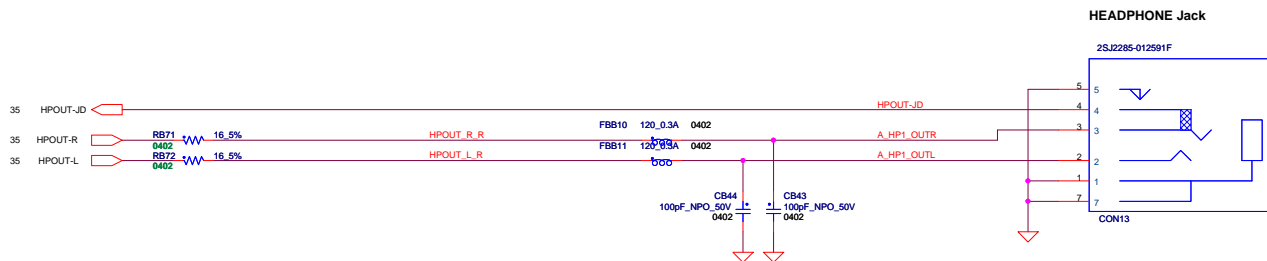
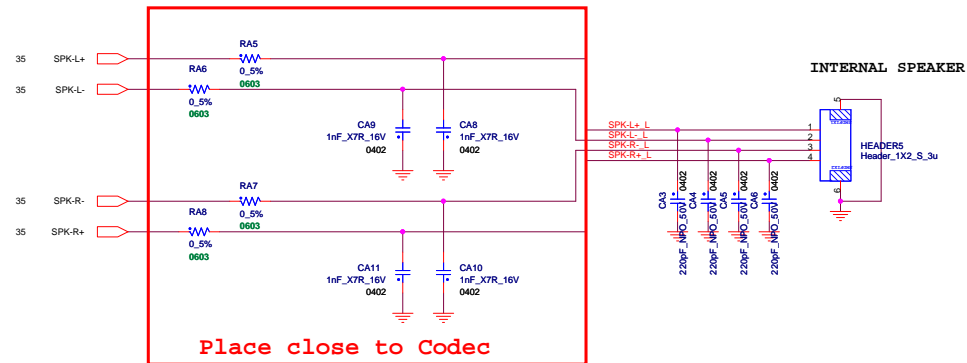
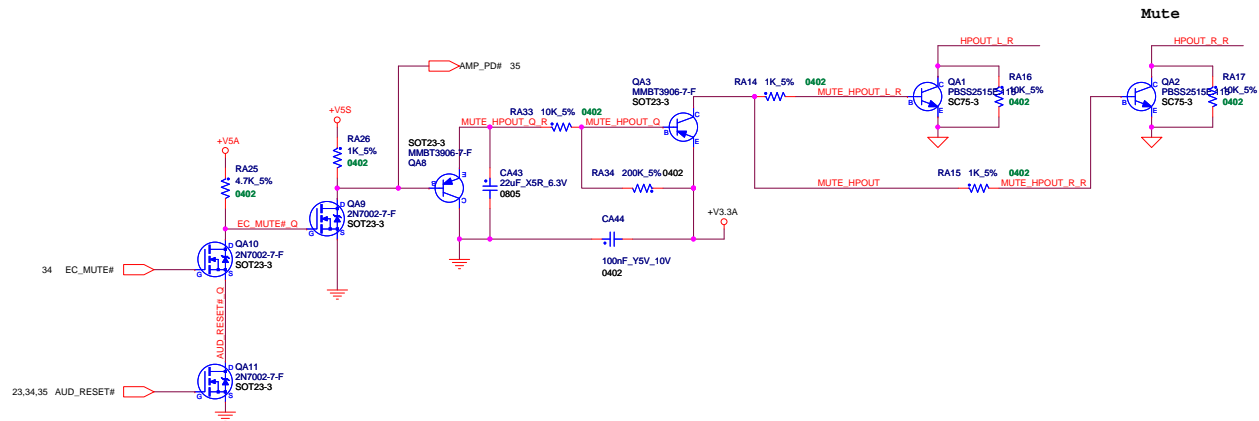


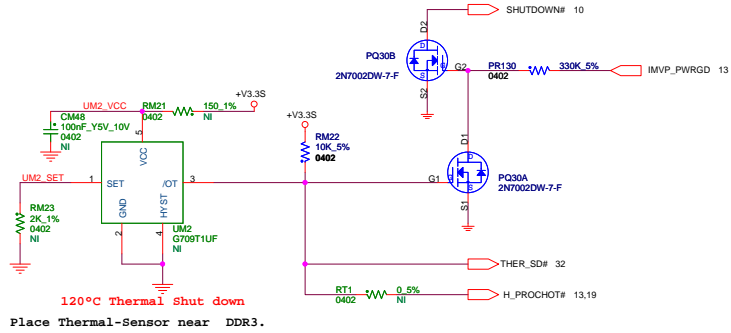
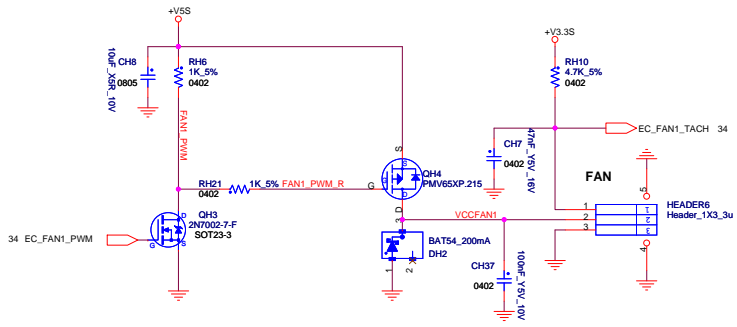
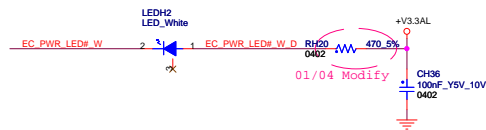
VERSION				
Phase	ID2	ID1	ID0	
Pre-DB	0	0	0	
DB	0	0	1	
SI	0	1	0	
PV	0	1	1	
MV	1	0	0	

VERSION				
SKU	ID2	ID1	ID0	
DIS	0	0	0	
UMA	0	0	1	
PX	0	1	0	
	0	1	1	
DIS Giga	1	0	0	
UMA-Giga	1	0	1	
PX-Giga	1	1	0	
-Giga	1	1	1	

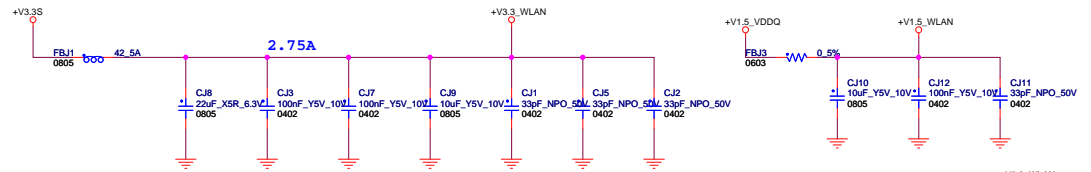
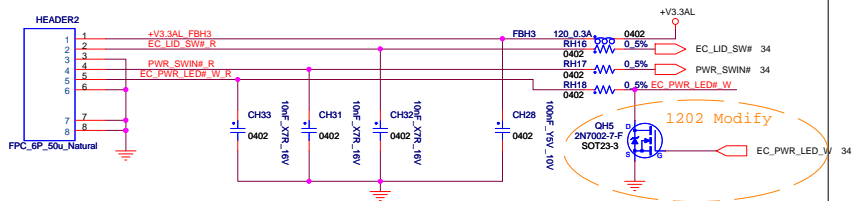
VERSION ID2	
w/ HDMI	0
w/o HDMI	1



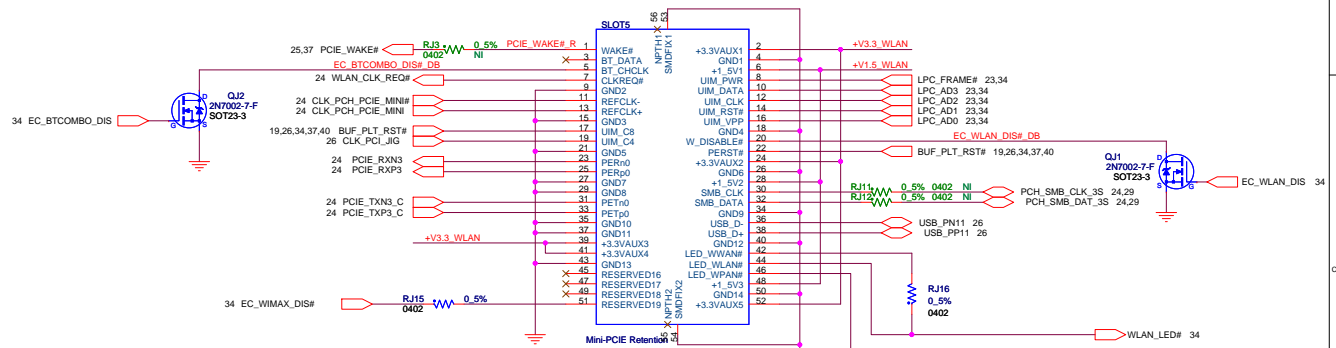




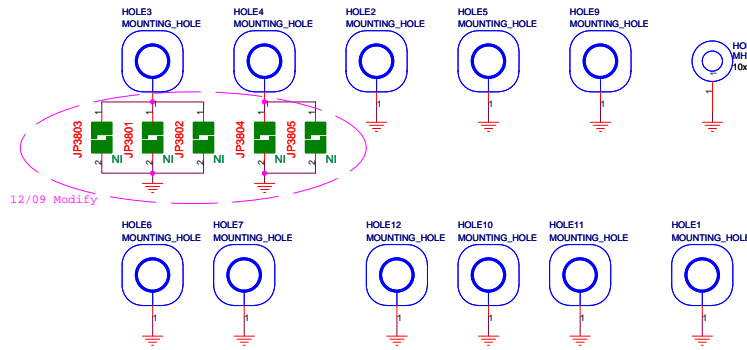
PWR Board CONN.



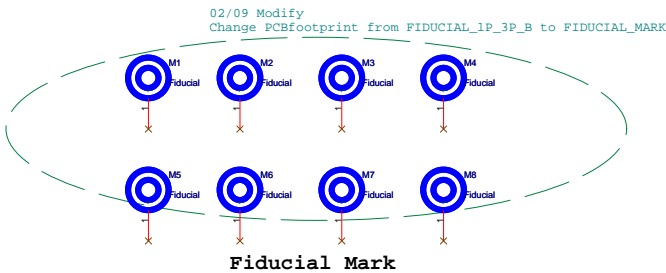
+1.5V=>0.5A Peak/0.375A Normal
+3.3Vaux=>2.75A Peak/1.1A Normal



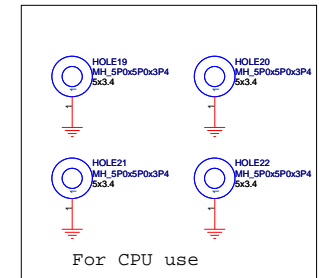
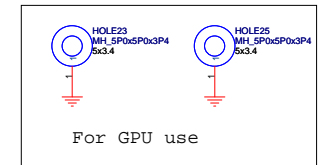
Half Mini Card for WLAN

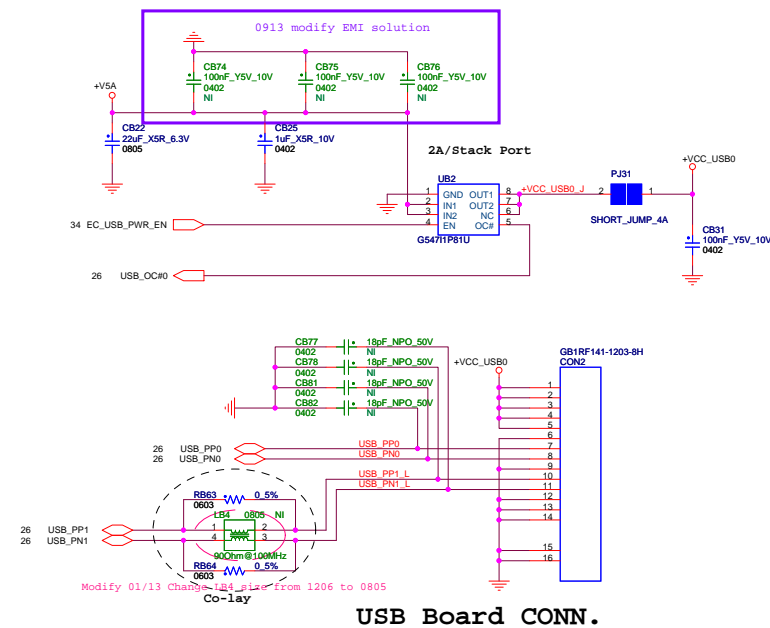
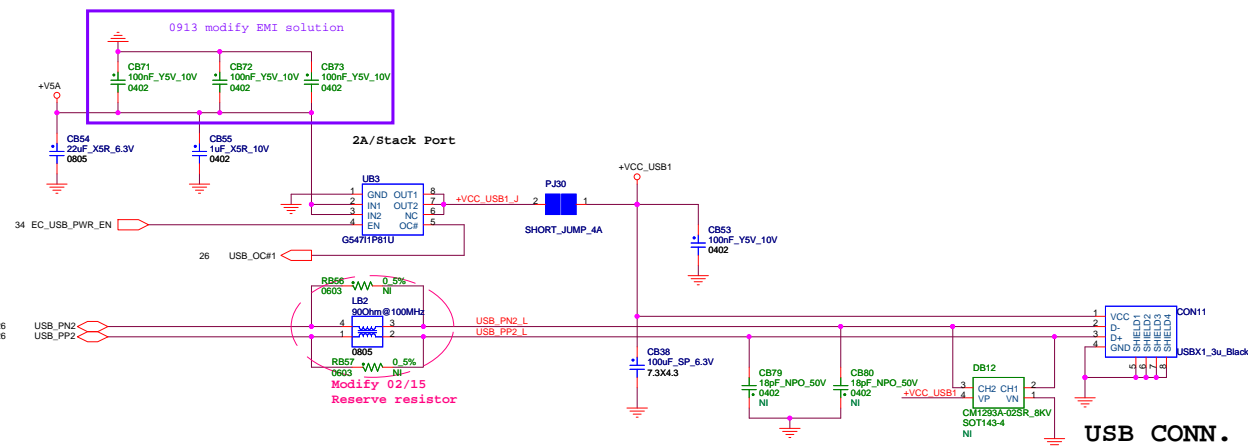


Mounting HOLE

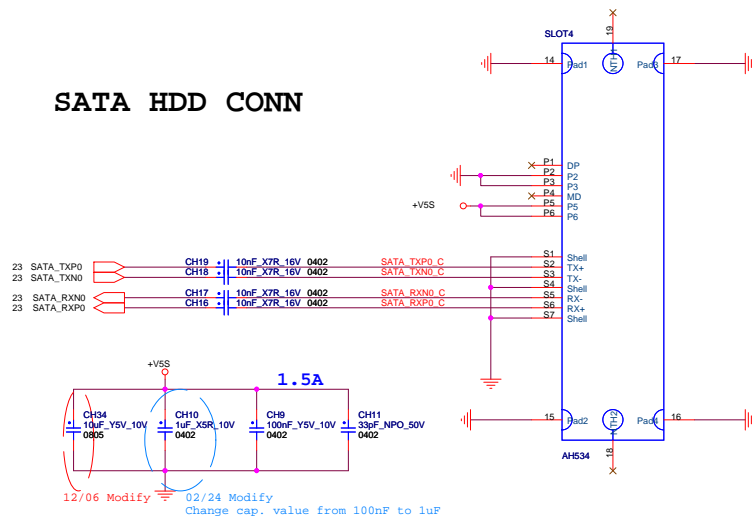


Fiducial Mark

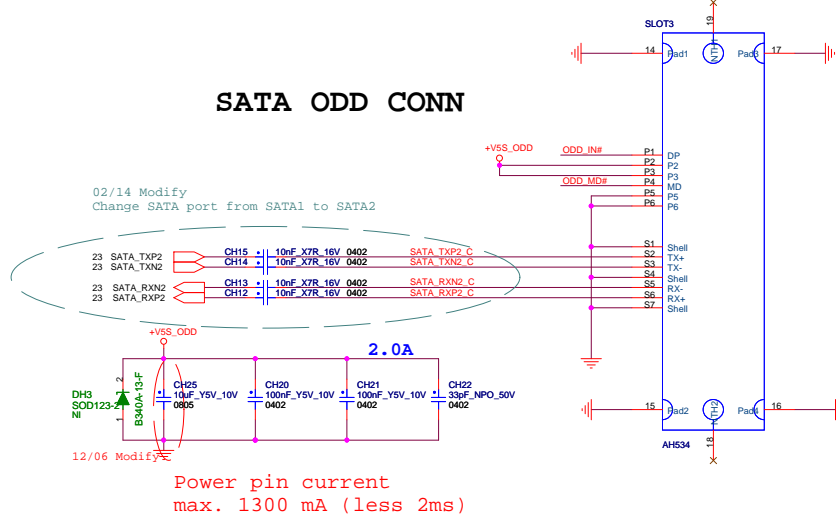




SATA HDD CONN



SATA ODD CONN



HDD/ODD Status LED

